

Towards Cosmic Neutrino Background detection

Symposium on the PTOLEMY project

23 Ottobre 2019 ore 14:00 - Dipartimento di Fisica - Aula Caianiello

Superconducting Nanowire Single Photon Detectors

SNSPDs

Giampiero Pepe

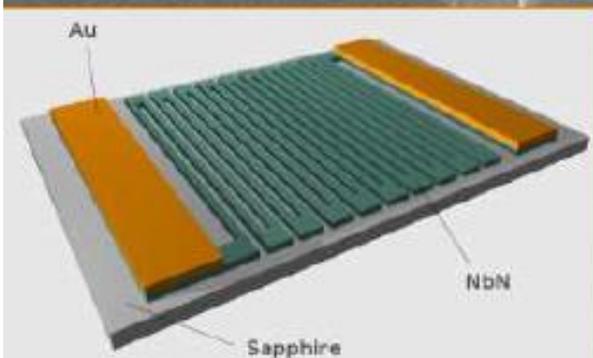


Università di Napoli *Federico II*
Dipartimento di Fisica «E. Pancini»
Complesso Universitario Monte Sant'Angelo, Napoli
and
Istituto CNR SPIN Napoli



Outline

- Background and Introduction
- The role of sc materials
- Set-up & Measurements
- The origin of Dark Counts
- About Detection Efficiency
- Conclusions



Yang et al., IEEE TAS (2005)

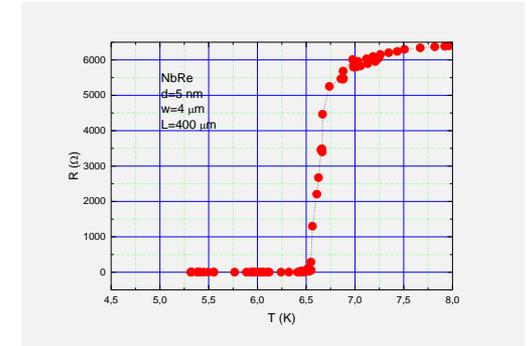
Goltsman et al., APL, (2001).

G Pepe,
PTOLEMY Meeting
Napoli 2019

Advantages of superconductive detectors

large number of quasiparticle creation by Cooper-pair breaking

- sharp normal - superconductor transition
- low heat capacitance
- kinetic inductance change
- wide choice of materials (A,Z,.....)
 - Superheated Superconducting Granules: **SSG**
 - Transition Edge Sensors: **TES**
 - Hot Electron Superconducting Photodetectors: **HESP**
 - Superconducting Tunnel Junctions: **STJ**
 - Josephson Junctions: **JJ**



Photon Detectors

Semiconductors

- a) One optical photon creates only one electron-hole pair (typical bandgap 1-2 eV)
- b) At low temperatures, relaxation and response times are long.

Superconductors

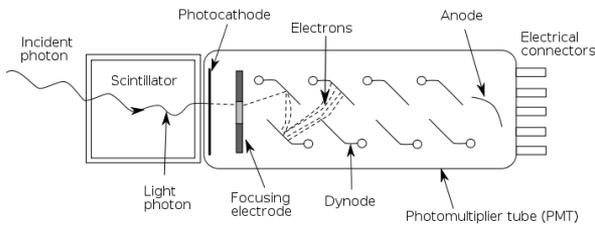
- a) One optical photon creates ~100–1000 excited electrons (superconducting gap ~ 2 meV for NbN)
- b) Relaxation is ultrafast even at low temperatures

Superconductivity is a macroscopic quantum phenomenon.

Low temperature environment reduces background noise and thermal fluctuations responsible for dark counts.

Single Photon Detectors (SPDs)

PMT

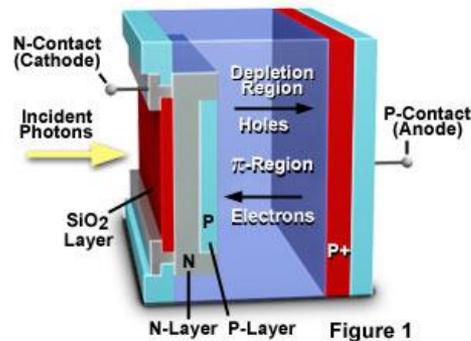


High Bias Voltage ~ KV

APD



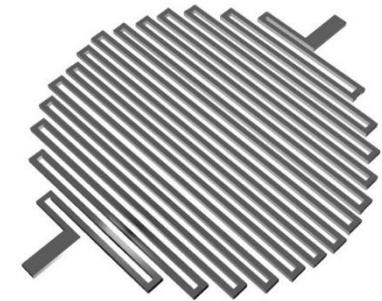
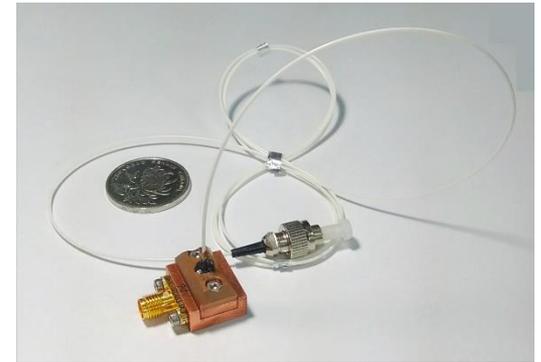
Avalanche Photodiode



Voltage Bias : ~ 10V

SNSPD

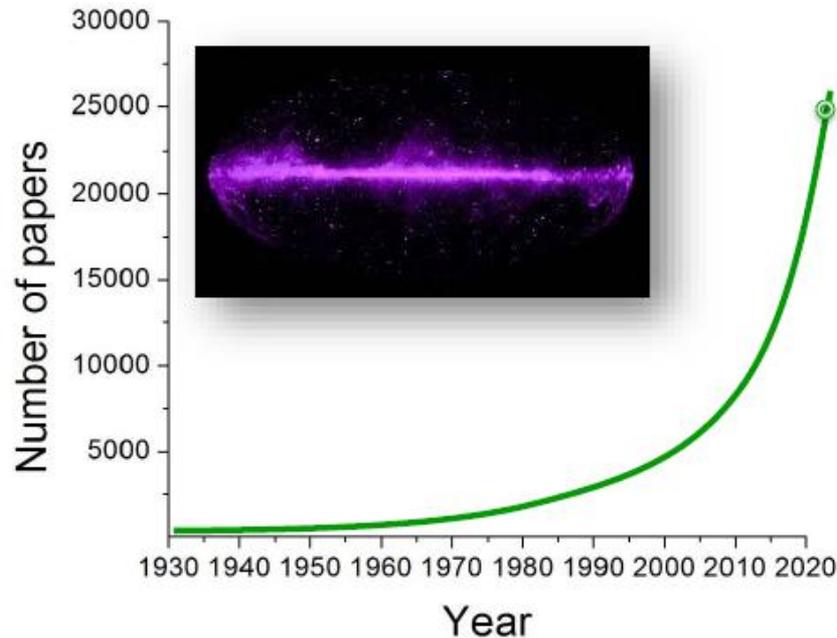
Since 2001



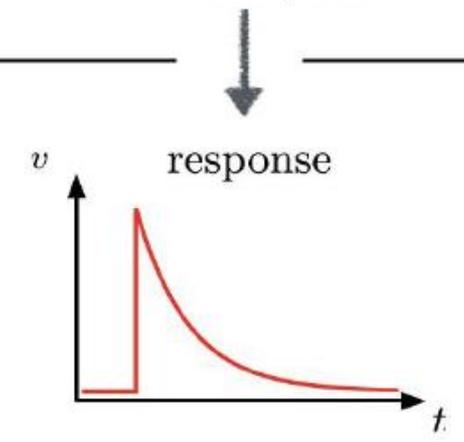
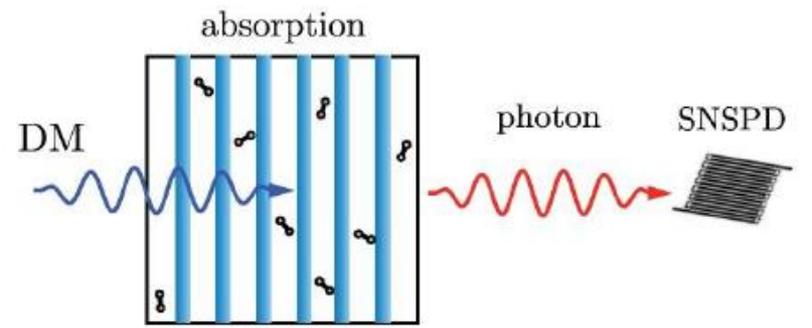
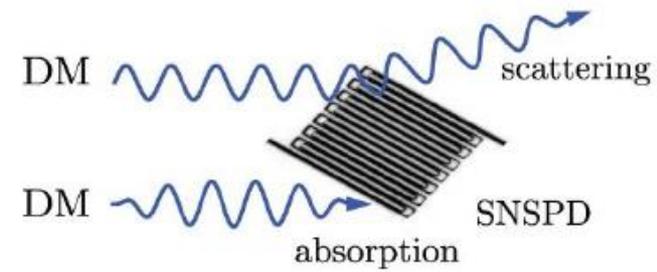
Current Bias : ~ 10 μ A

SNSPDs toward DM

Mass ranging 10 meV – 10 eV



Y. Hochberg, I. Charaev, S. W. Nam, V. Verma, M. Colangelo and K. K. Berggren, "Detecting Dark Matter with Superconducting Nanowires," arXiv:1903.05101 [hep-ph], submitted to PRL



Masha Baryakhtar, Junwu Huang, Robert Lasenby, Phys.Rev. D98 (2018) no.3, 035006 (arXiv:1803.11455)

Courtesy of I Charaev, LTD20



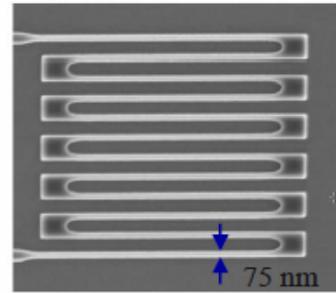
Dark-Matter Searching using superconducting nanowire



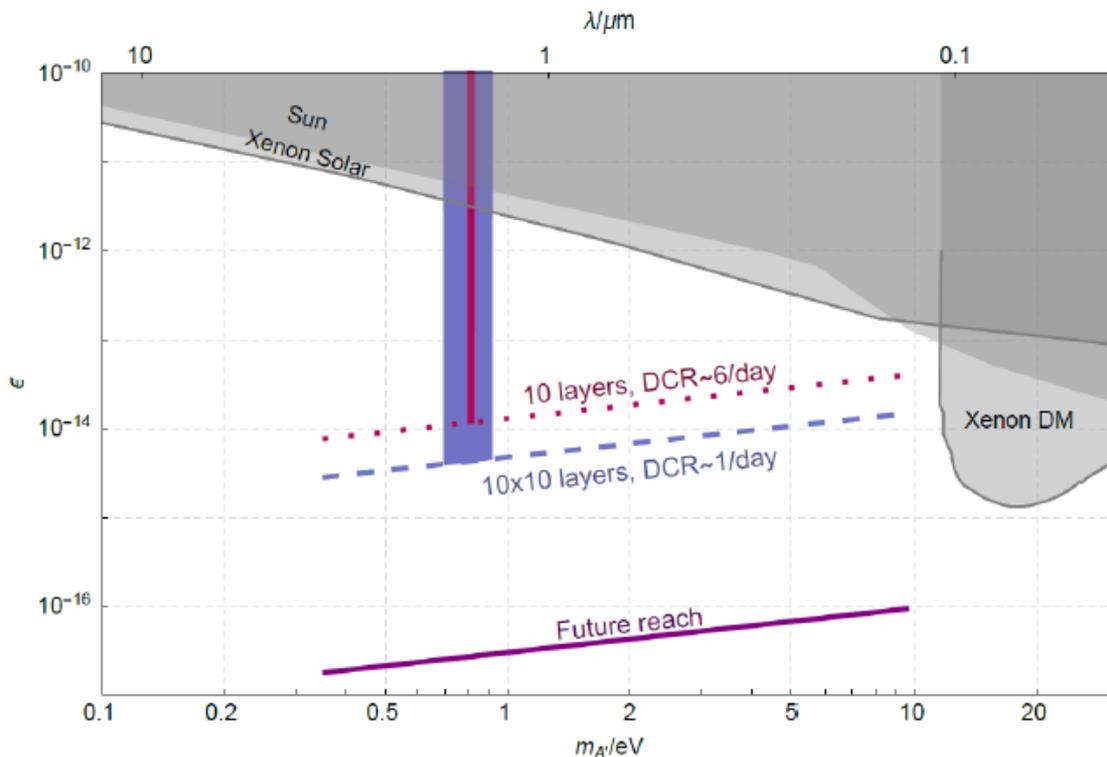
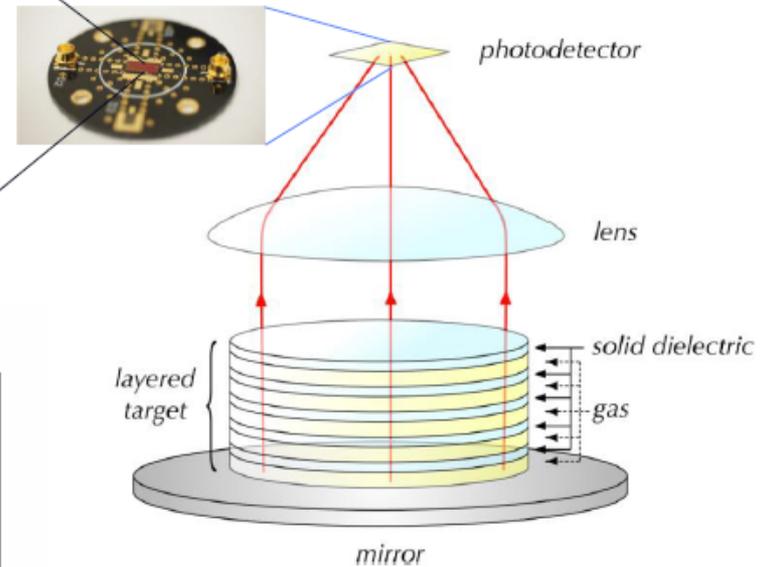
Collaboration of fundamental physics theorists, device designers, and system integrators and engineers:

- (1) Use quantum interference of dark matter to build up population in a single-photon state;
- (2) Use detector technology perfected for quantum-optics to sense photon.

superconducting detector



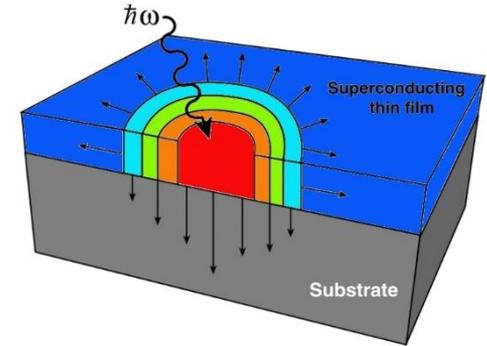
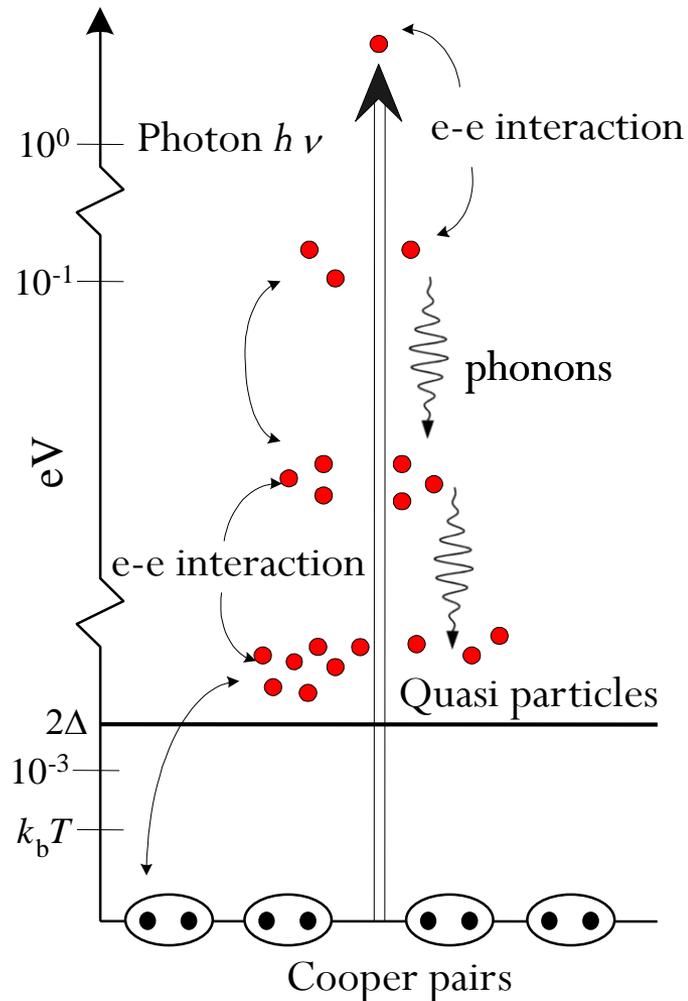
Dark-Matter Detector Concept



Key advantage of these detectors is low Dark Count Rate (DCR). Depending on number of layers in target, and achievable DCR, reach of experiment could extend well beyond what is possible today

Courtesy of I Charaev, LTD20

Cascade of broken Cooper pairs



- Photon breaks a cooper pair
- Thermalizes making $h\nu/\Delta$ qp's
- # gain but no E gain yet
- E resolution / photon # counting determined by shot noise
- Gain comes from change R or L

Refined Hot-Spot Model

Super-current density: $j_S = 2en_Sv_S$

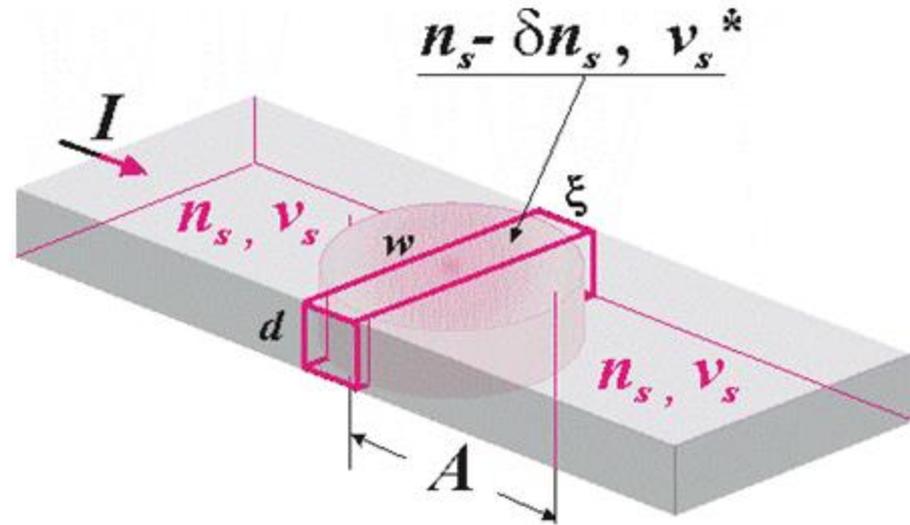
Critical-current density: $j_C = 2en_Sv_C$

Charge flow conservation

$$(n_S - \delta n_S)v'_S = n_Sv_S$$

Switching criteria

$$e(n_S - \delta n_S)v_S^* \geq e n_S v_C = j_C$$



$$v'_S = \frac{n_S}{n_S - \delta n_S} v_S$$

See: Semenov et al., Europ. Phys. J., 2005

Refined Hot-Spot Model

Super-c
Critical-

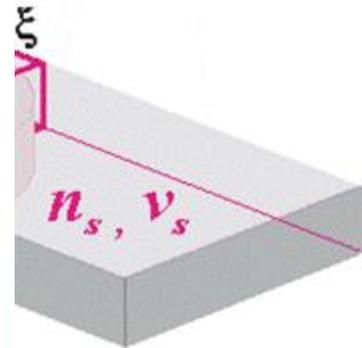
Minimum photon energy necessary to create a count event:

$$\varepsilon = \frac{hc}{\lambda_0} = \frac{3\sqrt{\pi}}{4\zeta} \Delta^2 W d N_0 \sqrt{D\tau} \left(1 - \frac{I_B}{I_C^d} \right)$$

Switching criteria

$$e (n_S - \delta n_S) v_S^* \geq e n_S v_C = j_C$$

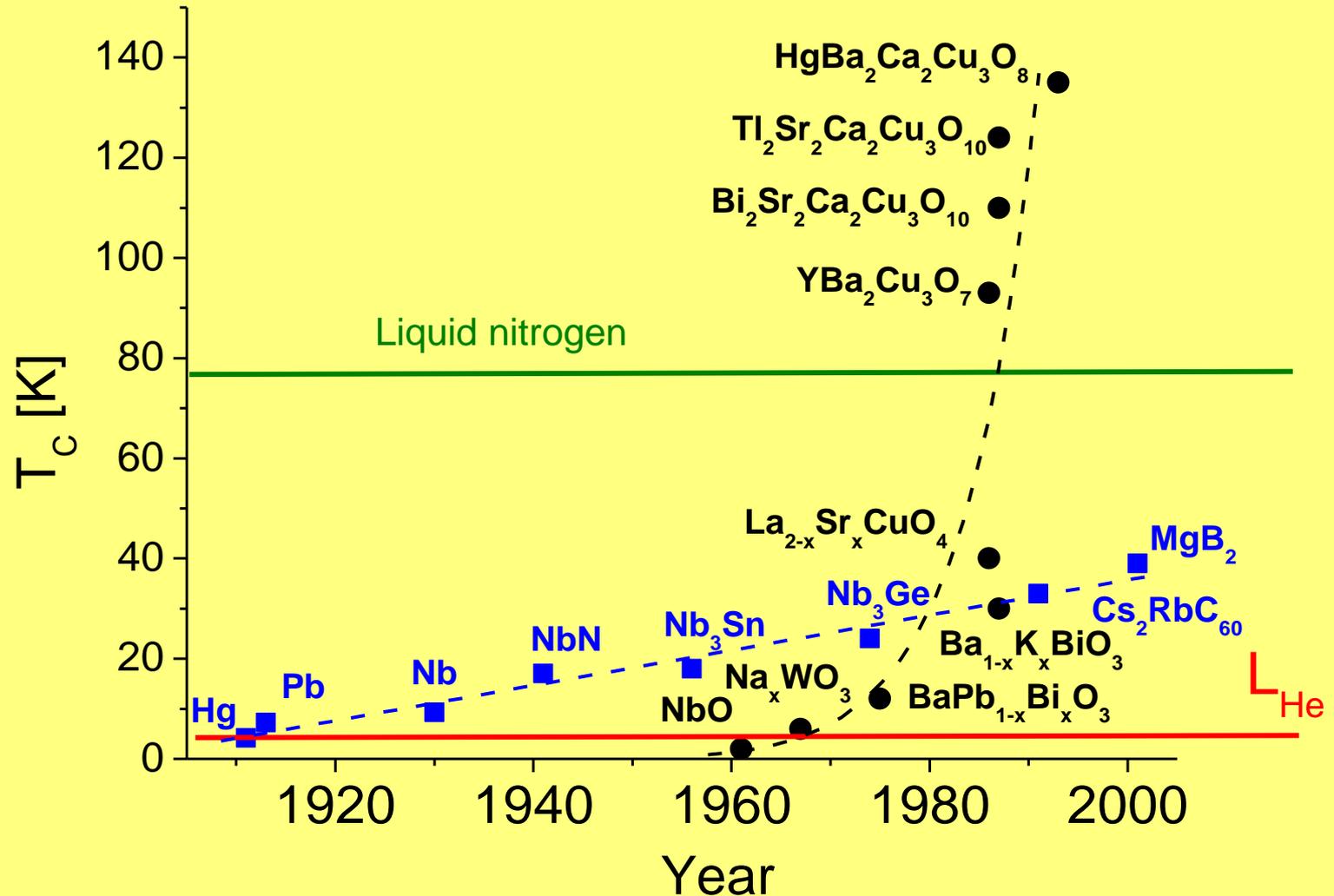
$$n_S - \delta n_S, v_S^*$$



$$\frac{n_S}{n_S - \delta n_S} v_S$$

See: Semenov et al., Europ. Phys. J., 2005

Superconducting Materials



SNSPD : Materials

The Silicides family

SSPD performance in the **mid- and far-IR ranges** can be improved further by using **narrow-gap superconductors** with a **low quasi-particle diffusivity**.

Materials	T_c K	T_c (4nm) K	ξ nm	λ nm	ρ $\mu\Omega$ cm	N_o 10^{21} states $eV^{-1} cm^{-3}$	D cm^2/s	J_c MA/cm ²	τ_0 ps
NbN	16	9-11	5	380 900-1300	100-240	56	0.5	6-7	60
$W_{0.75}Si_{0.25}$	5	3.7	7,3	768		26	0,70	0.8	
$Mo_{0.8}Si_{0.2}$	7.5	4.3		734	198			1.3	

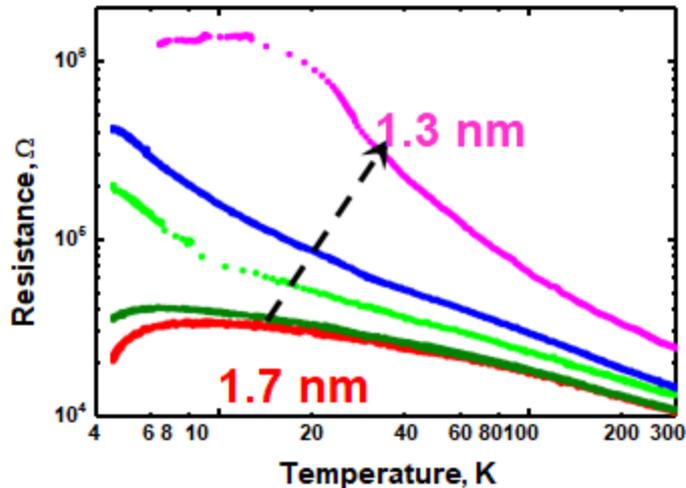
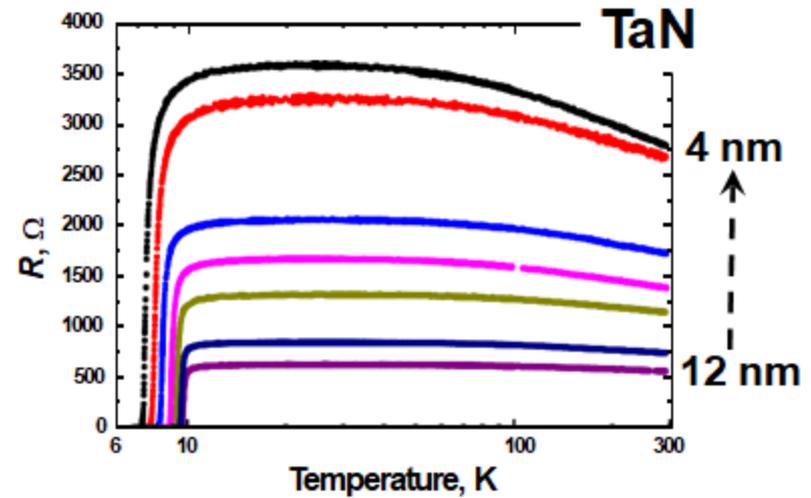
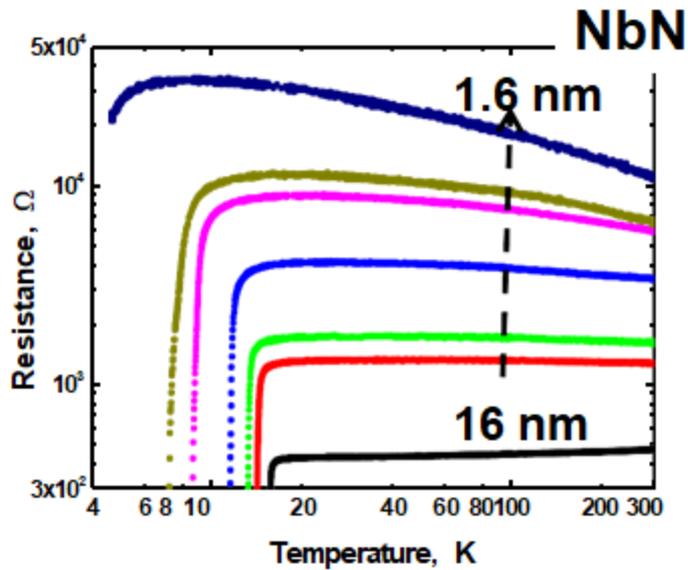
- amorphous → better integration with integrated optical cavity
- larger hot-spot and energy sensitivity
- better quantum efficiency

WSi - The new player: the highest system detection efficiency (**93%**)

Appl. Phys. Lett. 105, 122601 2014, *Phys. Rev B* 94, 174509 (2016) and *Nature Photonics* 7 211 (2013)

MoSi - **higher temperatures** for efficient SSPD operation, *Supercond. Sci. Technol.* 27 095012 (2014)

SNSPD : Materials



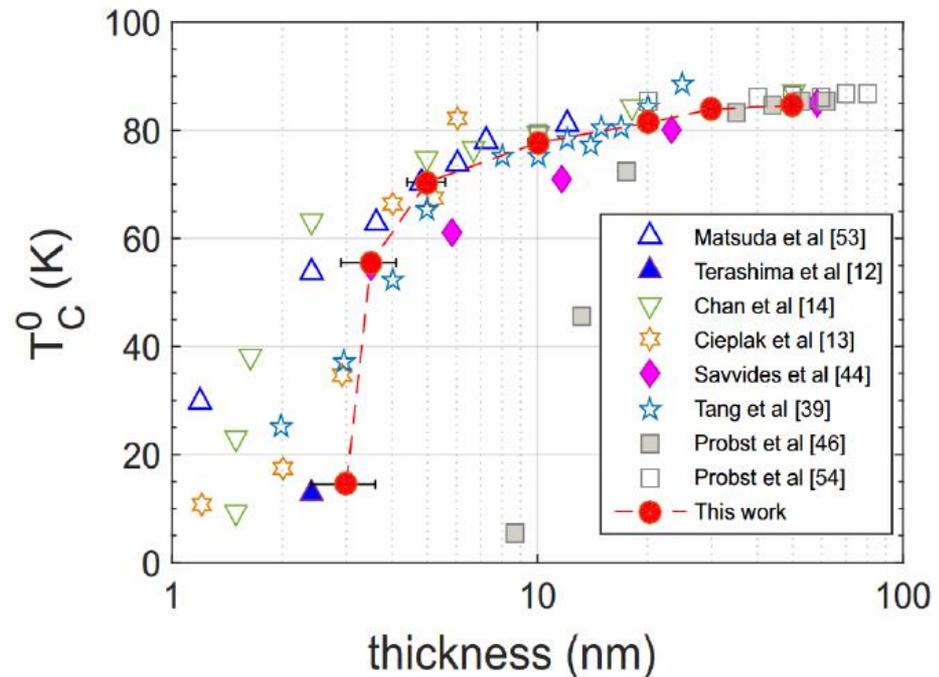
$$\varepsilon = \frac{hc}{\lambda_0} = \frac{3\sqrt{\pi}}{4\zeta} \Delta^2 W d N_0 \sqrt{D\tau} \left(1 - \frac{I_B}{I_C^d} \right)$$

SNSPD : Materials

YBCO films down to few nm

Slightly overdoped YBCO on MgO(110)

- Our films show good quality down to $t=5$ nm
- We have shown that the same also holds for underdoped films



R. Arpaia, ..., T. Bauch and *FL Phys. Rev. B* **96**, 064525 (2017)

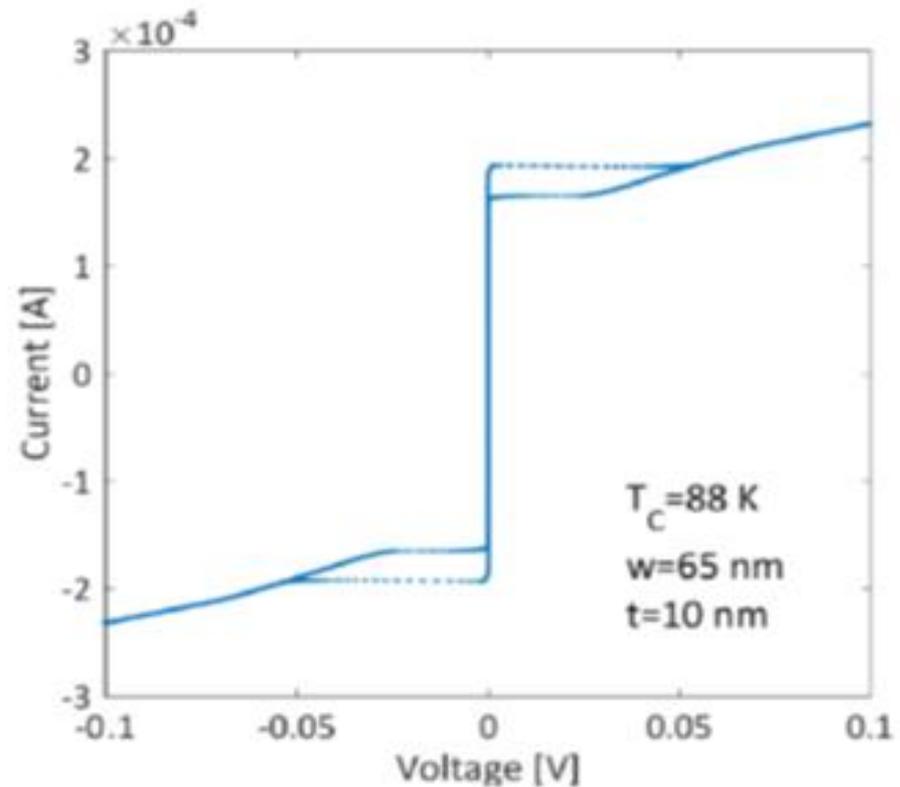
Courtesy of F Lombardi

SNSPD : Materials

YBCO films down to few nm

Slightly overdoped YBCO on MgO(110)

- Our films show good quality down to $t=5$ nm
- We have shown that the same also holds for underdoped films



Courtesy of F Lombardi

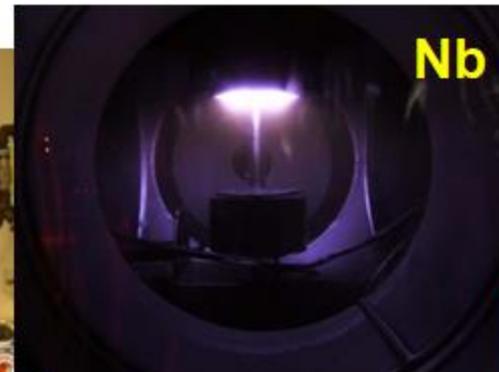
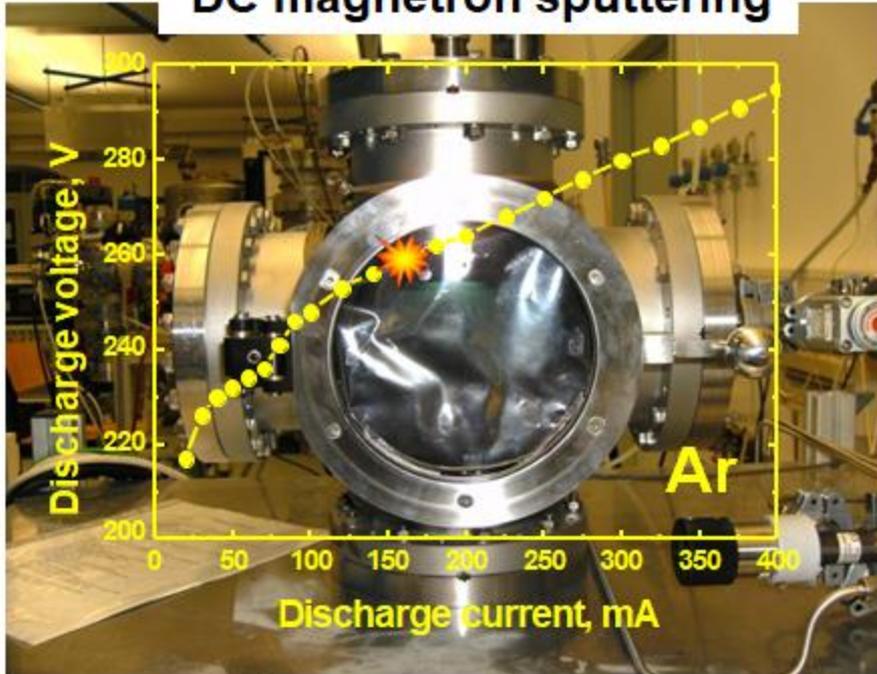
Material choice

Small energy gap superconductors:

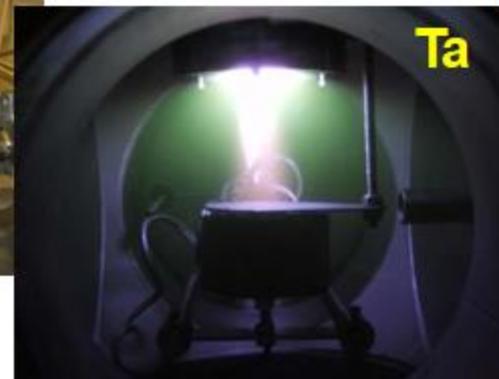
	Al	Ti	Nb	Ta
T_C, K	2	0.4	9.3	4.5

$$\varepsilon = \frac{hc}{\lambda_0} = \frac{3\sqrt{\pi}}{4\zeta} \Delta^2 W d N_0 \sqrt{D\tau} \left(1 - \frac{I_B}{I_C^d} \right)$$

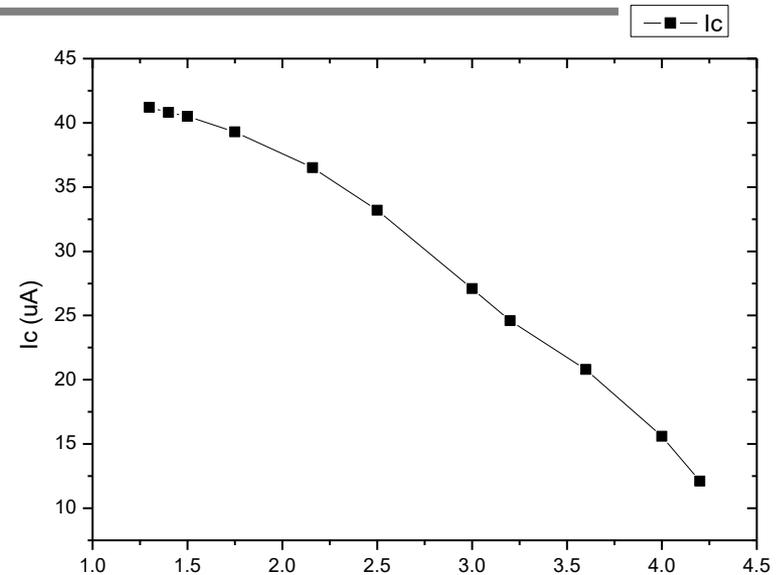
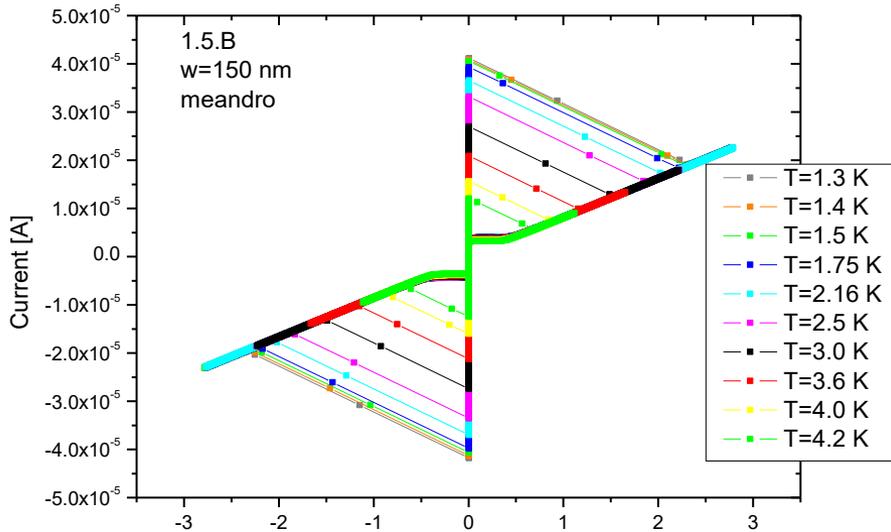
DC magnetron sputtering



- 2 inch Nb, Ta target
- $t^\circ = 750\text{ C}$
- $P_{Ar} = 3.5 \cdot 10^{-3}\text{ mbar}$



SNSPD : Materials

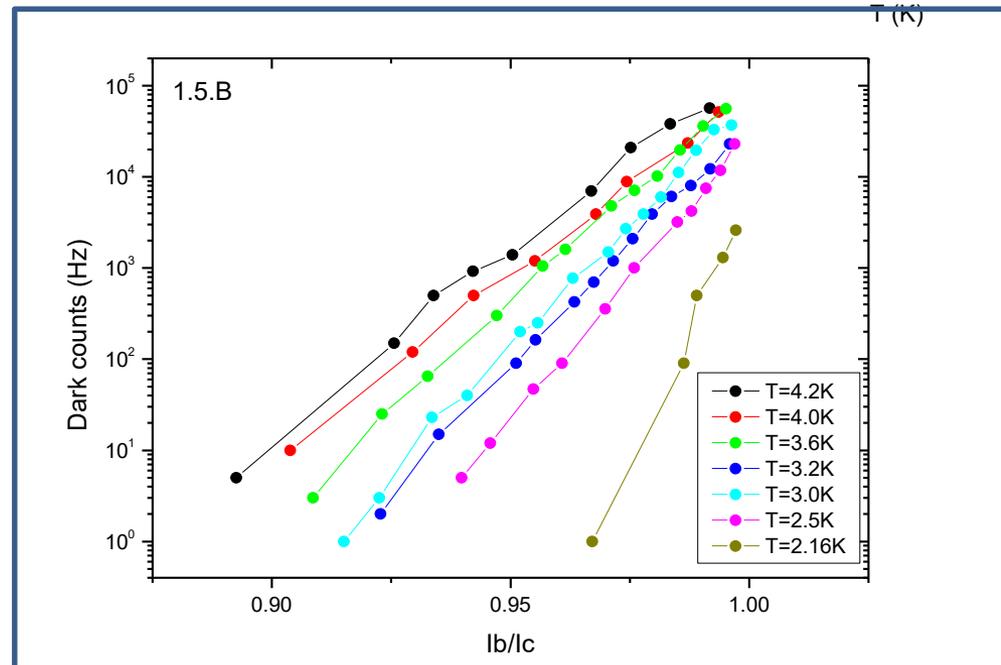


$$J_c = 3 \text{ MA/cm}^2 \text{ Voltage [V]}$$

T=1.3 K

MoSi thin films (8nm)

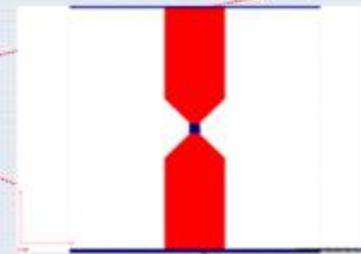
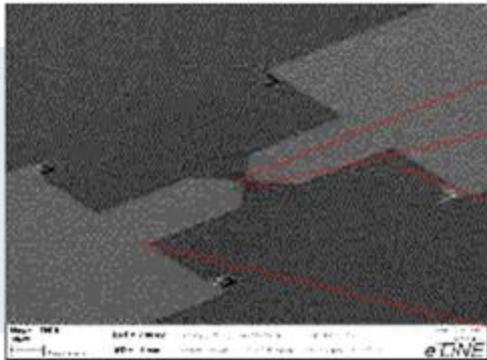
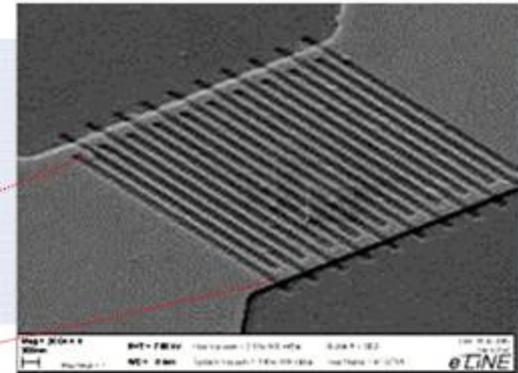
Naples



Fabrication

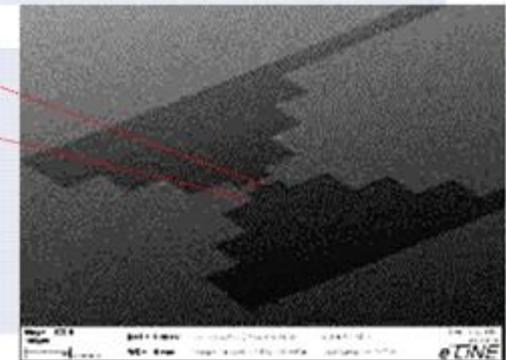
Patterning by electron beam lithographie and reactive ion milling

Detector structure

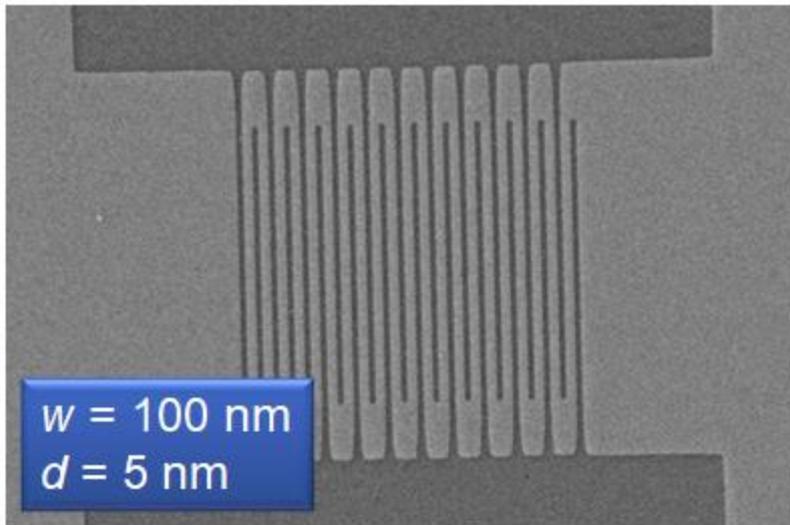


Contact pads

Coplanar readout



Current crowding effect



Superconductor:

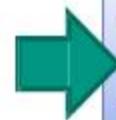
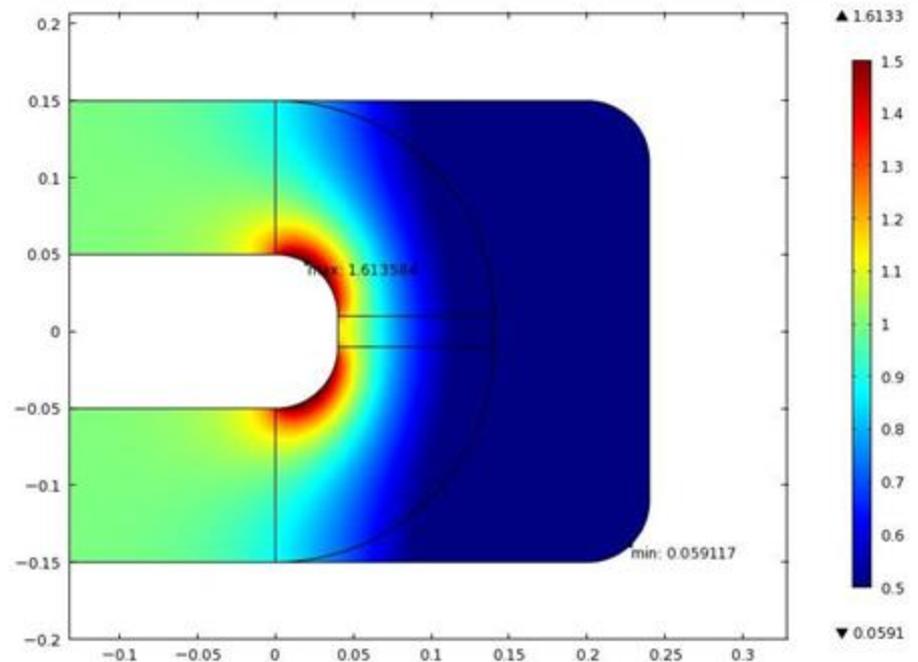
For $w, d < \lambda$ (London penetration depth)

- Uniform current distribution, only defined by geometry
- Local current density at inner edge exceeds density on the straight lines by $>50\%$!

Henrich et al., Phys. Rev. B 86, 144504 (2012)

Spectral detection efficiency of SNSPD

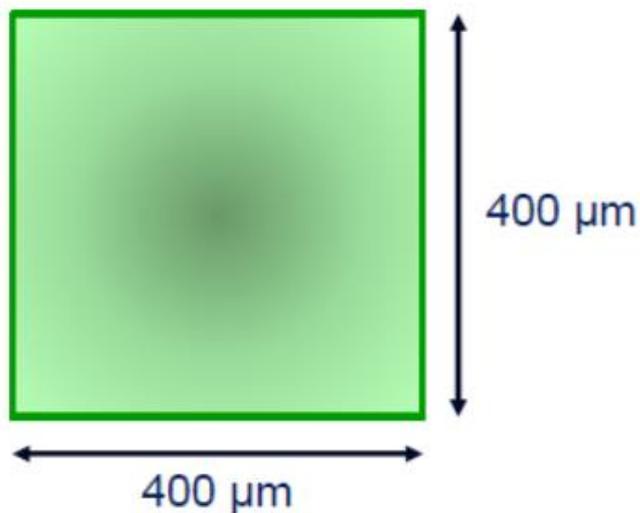
- small cross section wd
- High I_{bias}/I_C ratio



Current crowding can be reduced if turns have low angle and large radius

Fabrication

Patterning by electron beam lithographie and reactive ion milling

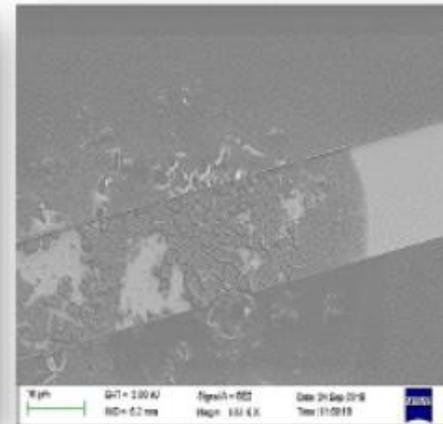
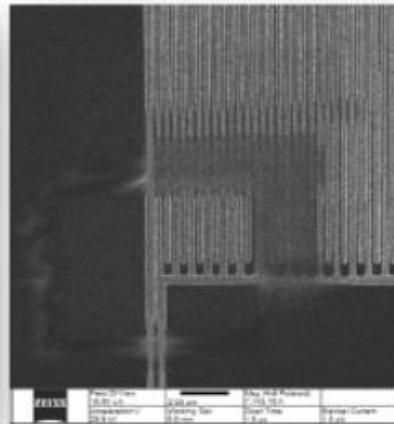
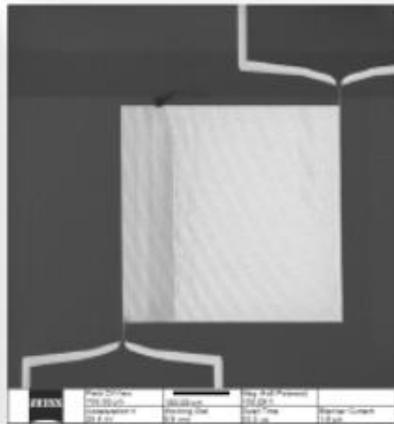
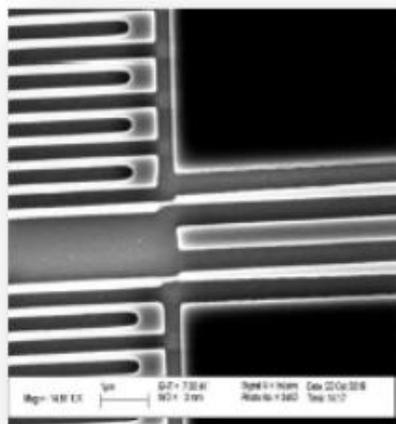


High probability of defects

- Cross-section variations: non-uniformity of the thickness or width of the film
- Nanowire edge defects or internal structural defects
- Current-crowding

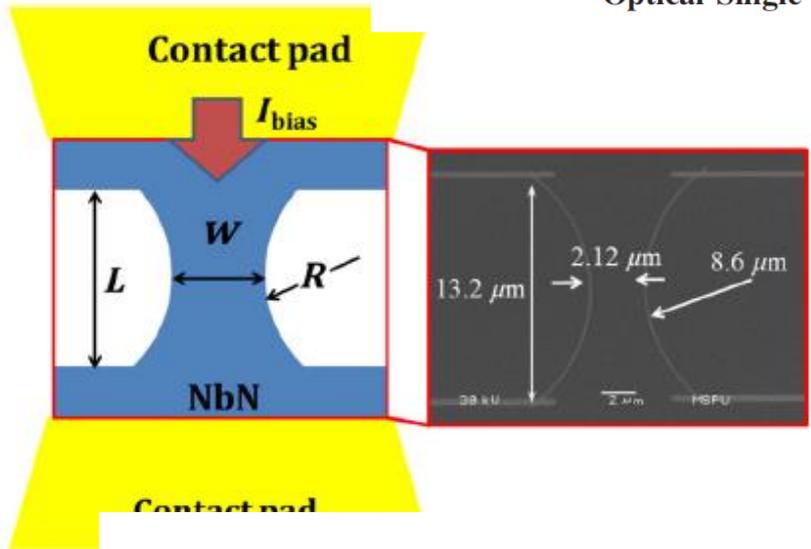
Requirements

- Long-term stability of electron-beam parameters and long-term suppression of external acoustic, mechanic, and electro-magnetic interferences
- Uniformity of resist

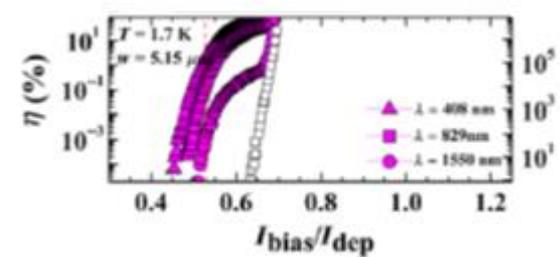
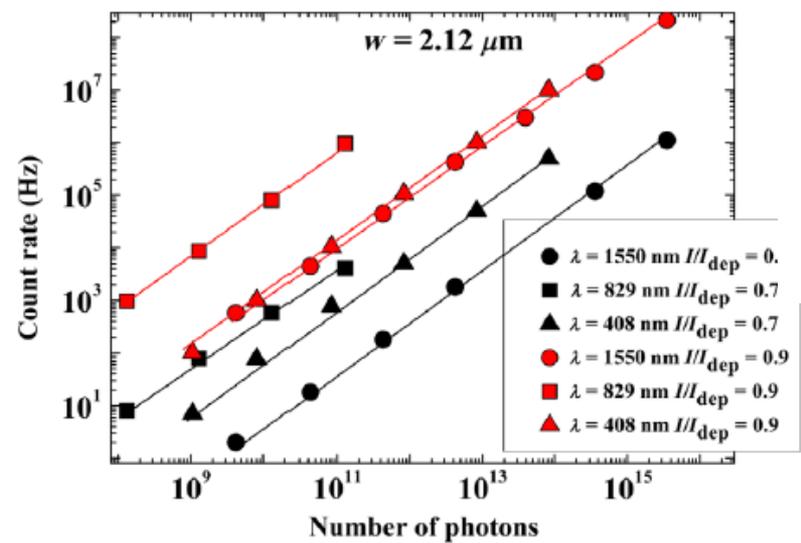


Good news?!

Optical Single-Photon Detection in Micrometer-Scale NbN Bridges



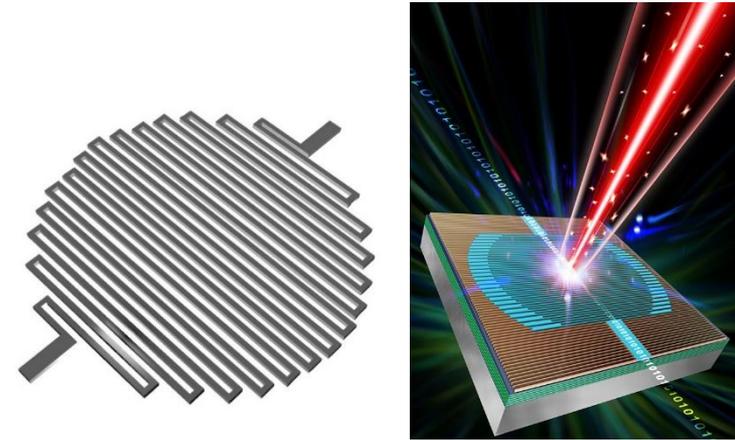
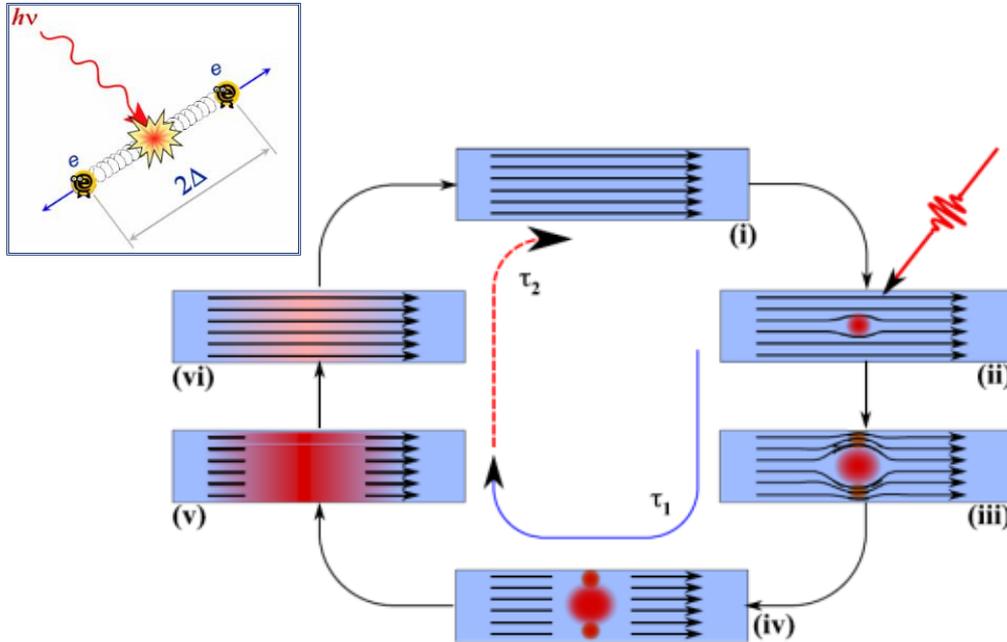
Width (μm)	T_c (K)	ρ (20 K) ($\mu\Omega \text{ cm}$)	j_c (4.2 K) (A/cm^2)
0.53	8.25	386	3.16×10^6
1.61	8.35	396	2.74×10^6
2.12	8.5	393	3.75×10^6
3.07	8.35	398	3.06×10^6
4.04	8.35	402	2.52×10^6
5.15	8.35	427	2.28×10^6



Detection Mechanism

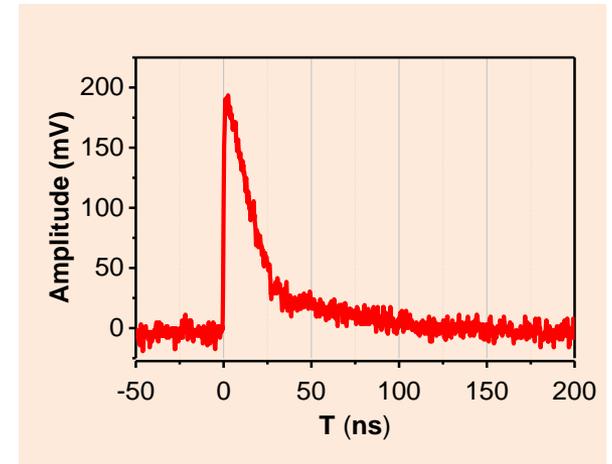
Cooper pair breaking by single photon

Goltsman et al, Appl Phys Lett, 2001, 79:705



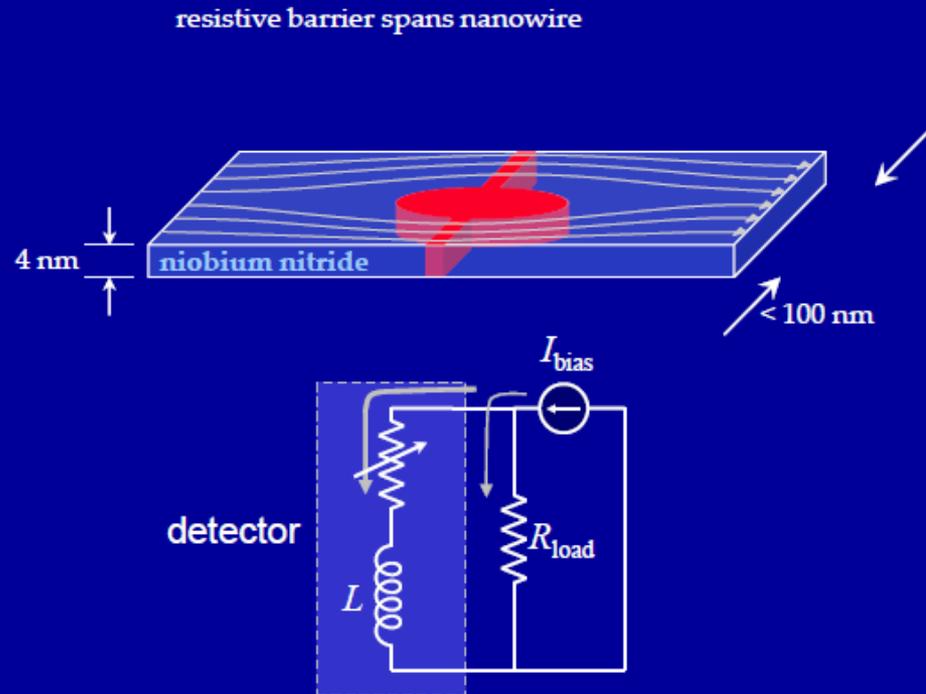
Photon energy vs Superconducting gap/Cooper Pair energy
 $h\nu$ (1eV) vs 2Δ (6.4 meV)

* Ultrathin nanowire (~5 nm thick and ~100 nm wide)



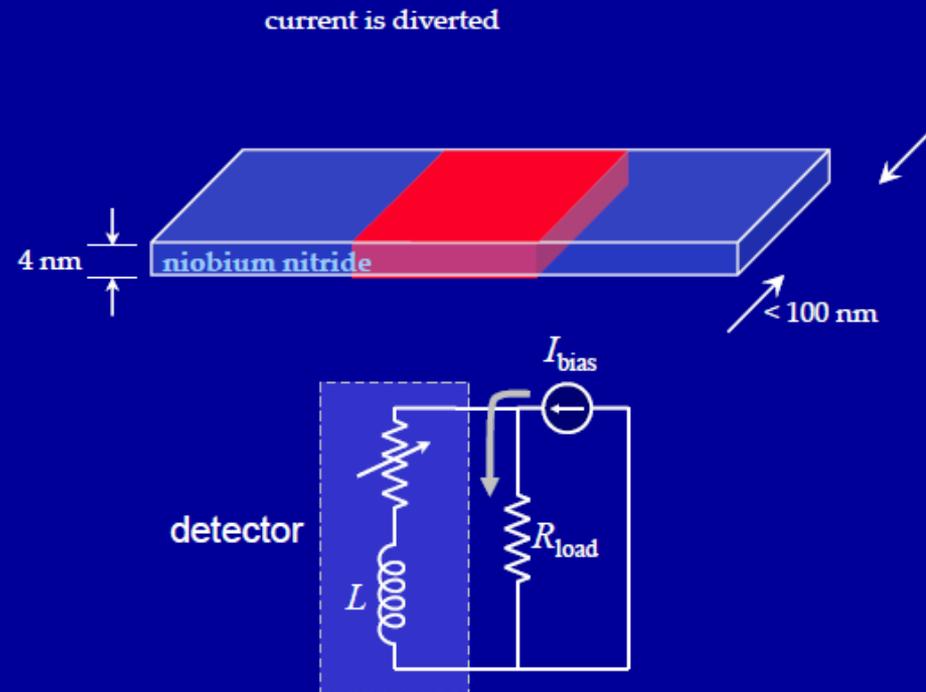
Detection Mechanism

Detection Mechanism Explanation



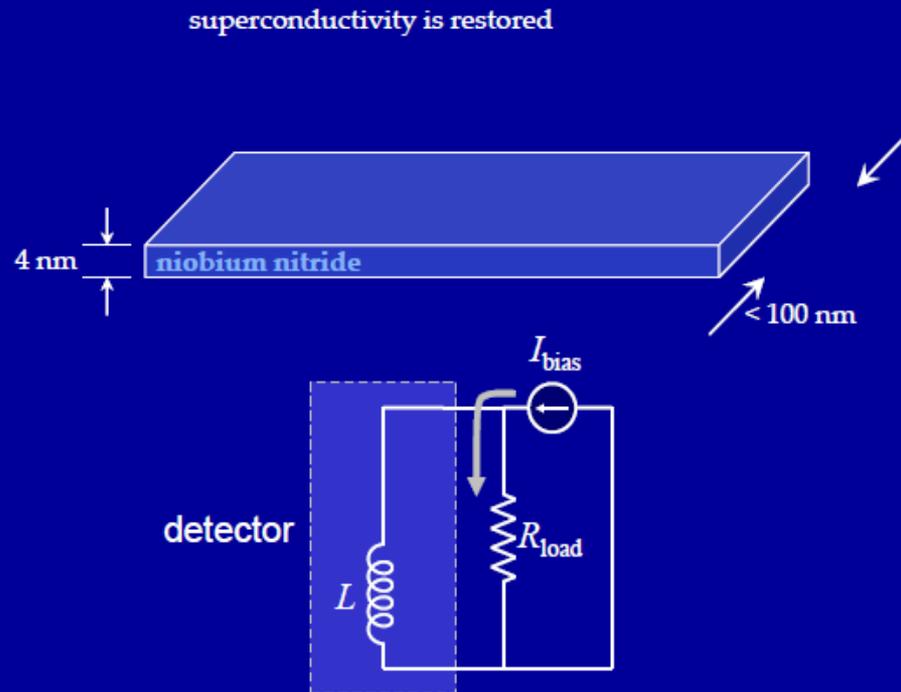
Detection Mechanism

Detection Mechanism Explanation

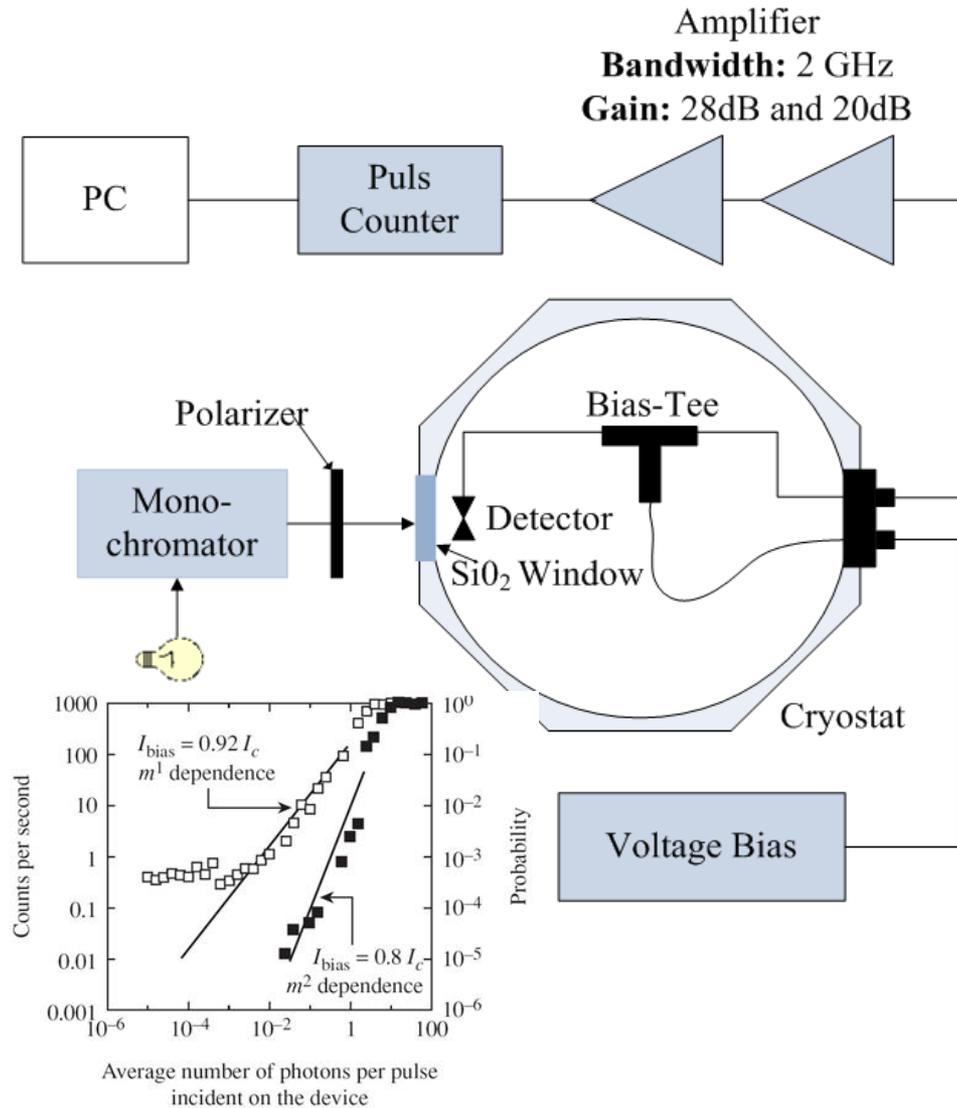


Detection Mechanism

Detection Mechanism Explanation



SNSPD - Experimental Setup



⁴He Bath Cryostat

- Vacuum chamber
- Liquid helium cooled
- Feed troughs for electrical contacts
- SiO₂ window for radiation input

Electrical Part

- RF-micro strip line, Coaxial line
- Bias-Tee for DC/AC coupling
- Low noise voltage source
- RF-amplifier

48 dB, 2 GHz bandwidth

- Pulse Counter (SR400, BW: 250 MHz)

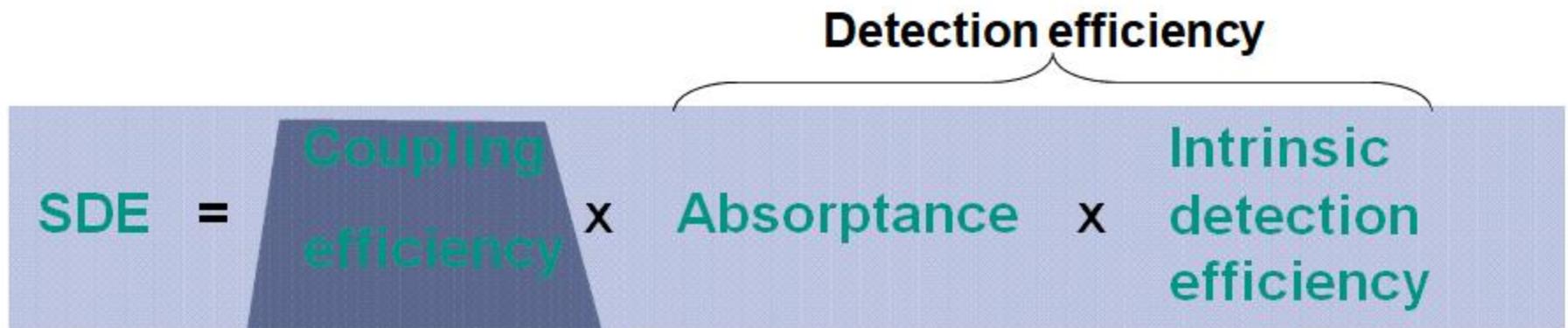
Radiation Source

- Optical range 400nm to 2000nm

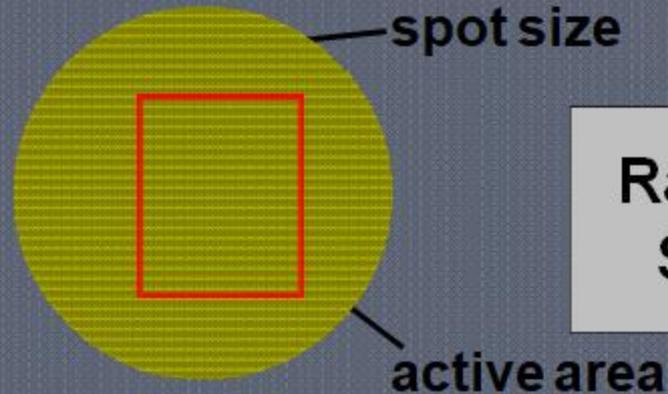
System Detection Efficiency

$$\text{SDE} = \text{Coupling efficiency} \times \text{Absorptance} \times \text{Intrinsic detection efficiency}$$

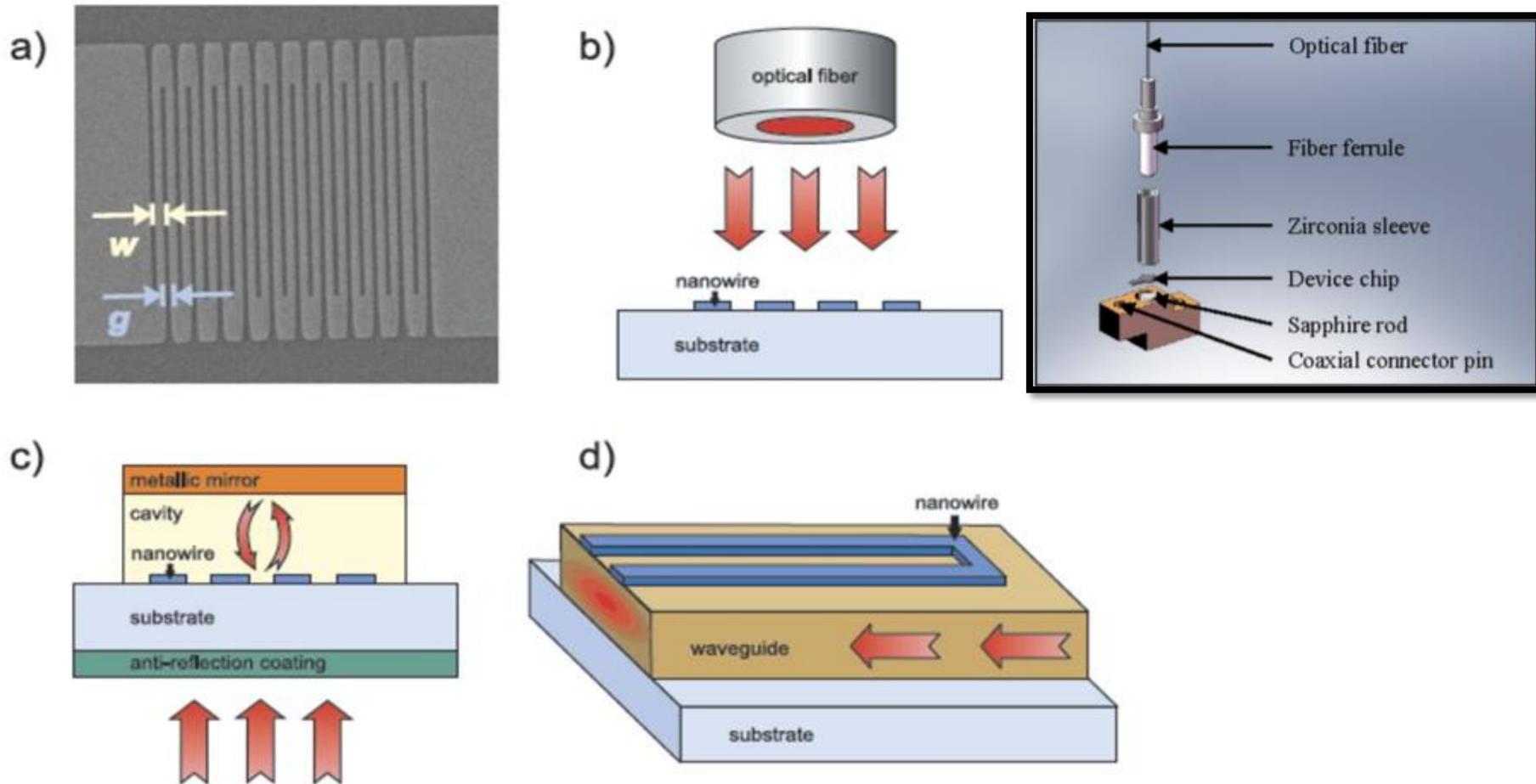
Detection efficiency

The equation is presented on a light blue background. A dark blue trapezoid is drawn behind the 'Coupling efficiency' term, tapering from left to right. A bracket above the 'Absorptance' and 'Intrinsic detection efficiency' terms is labeled 'Detection efficiency'.

Loss by reflection, bad focusing, attenuation

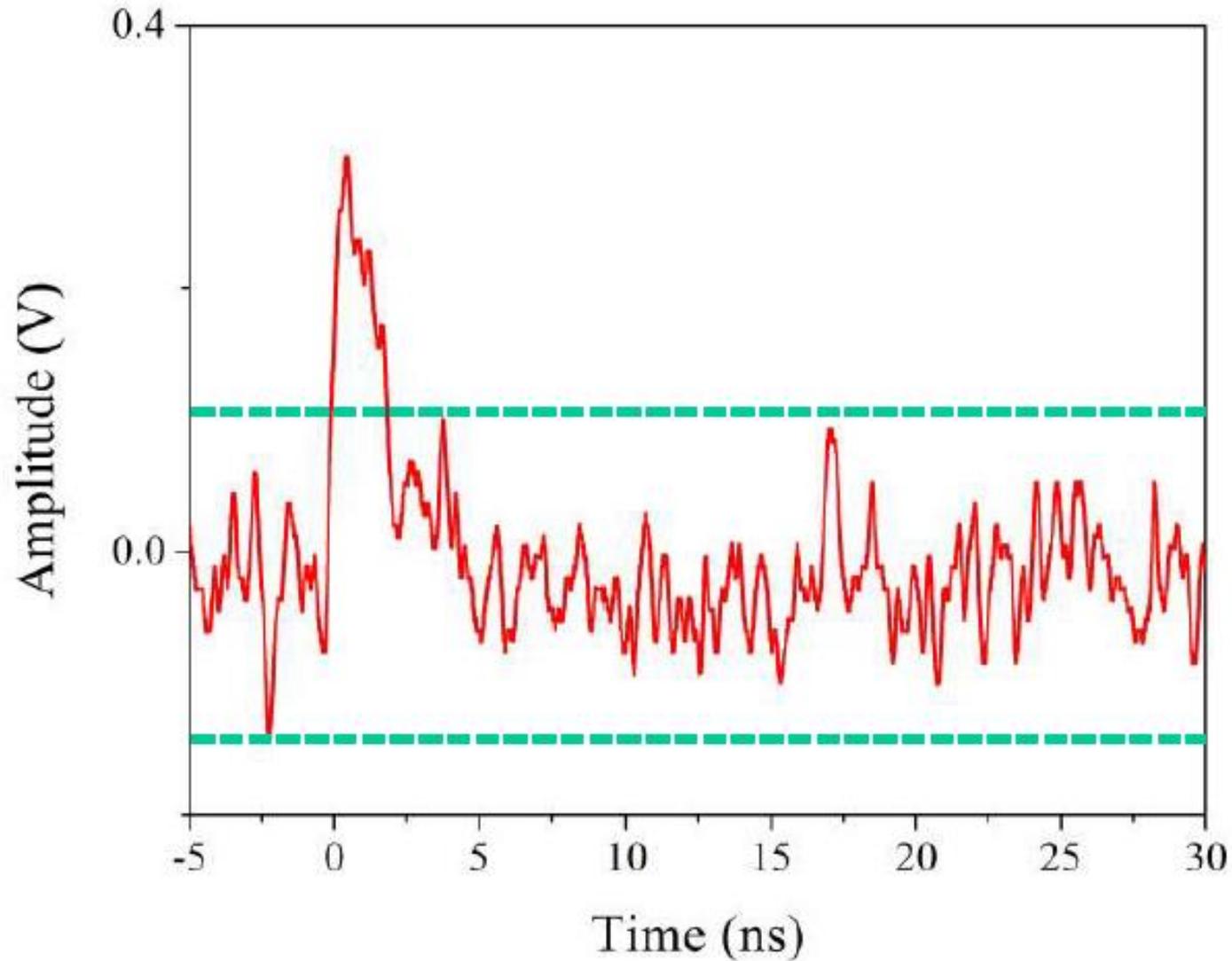


Improved optical coupling

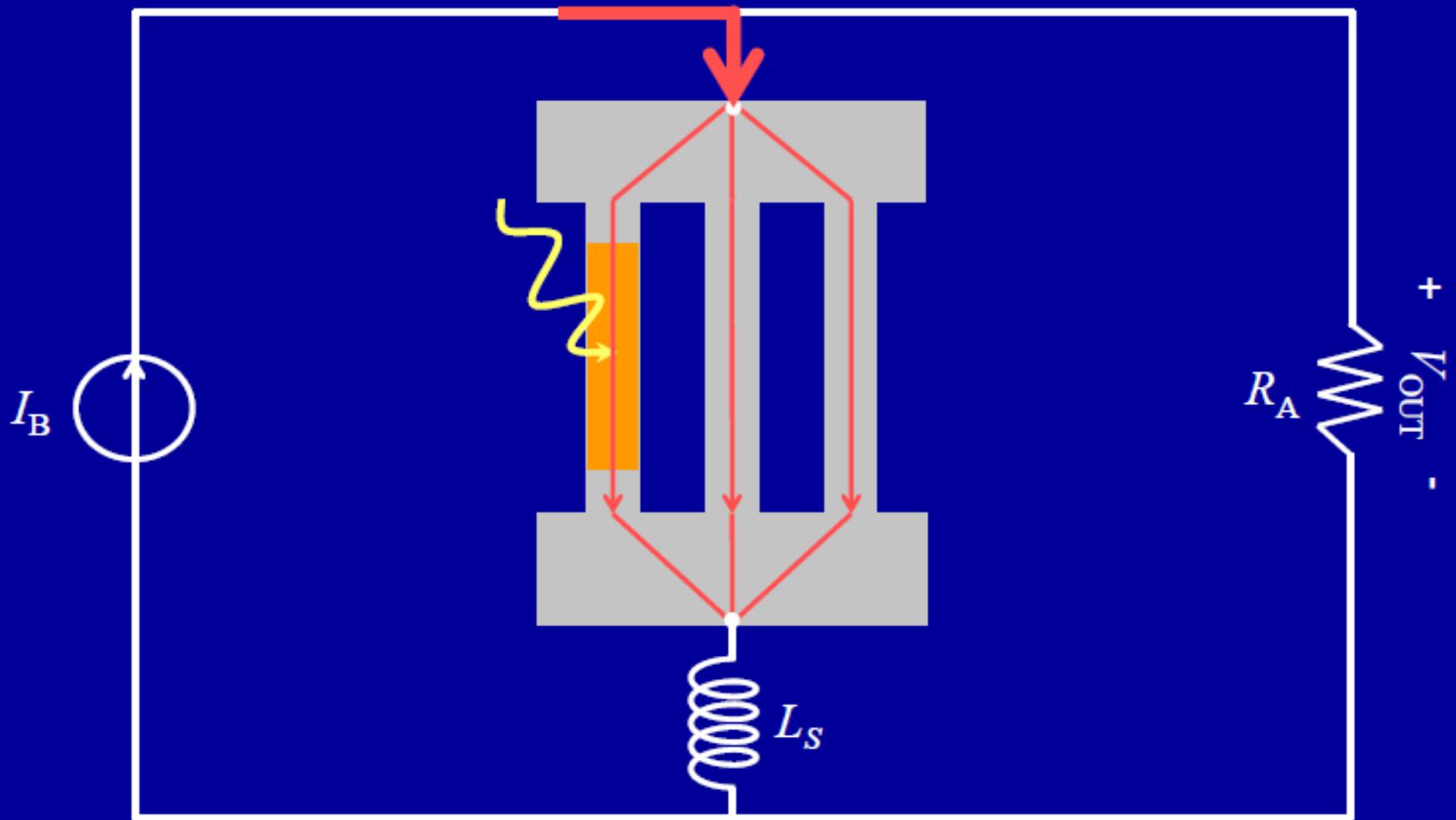


Ref.: C. M. Natarajan et al., Superconductor Science and Technology, 25, 063001, 2012.

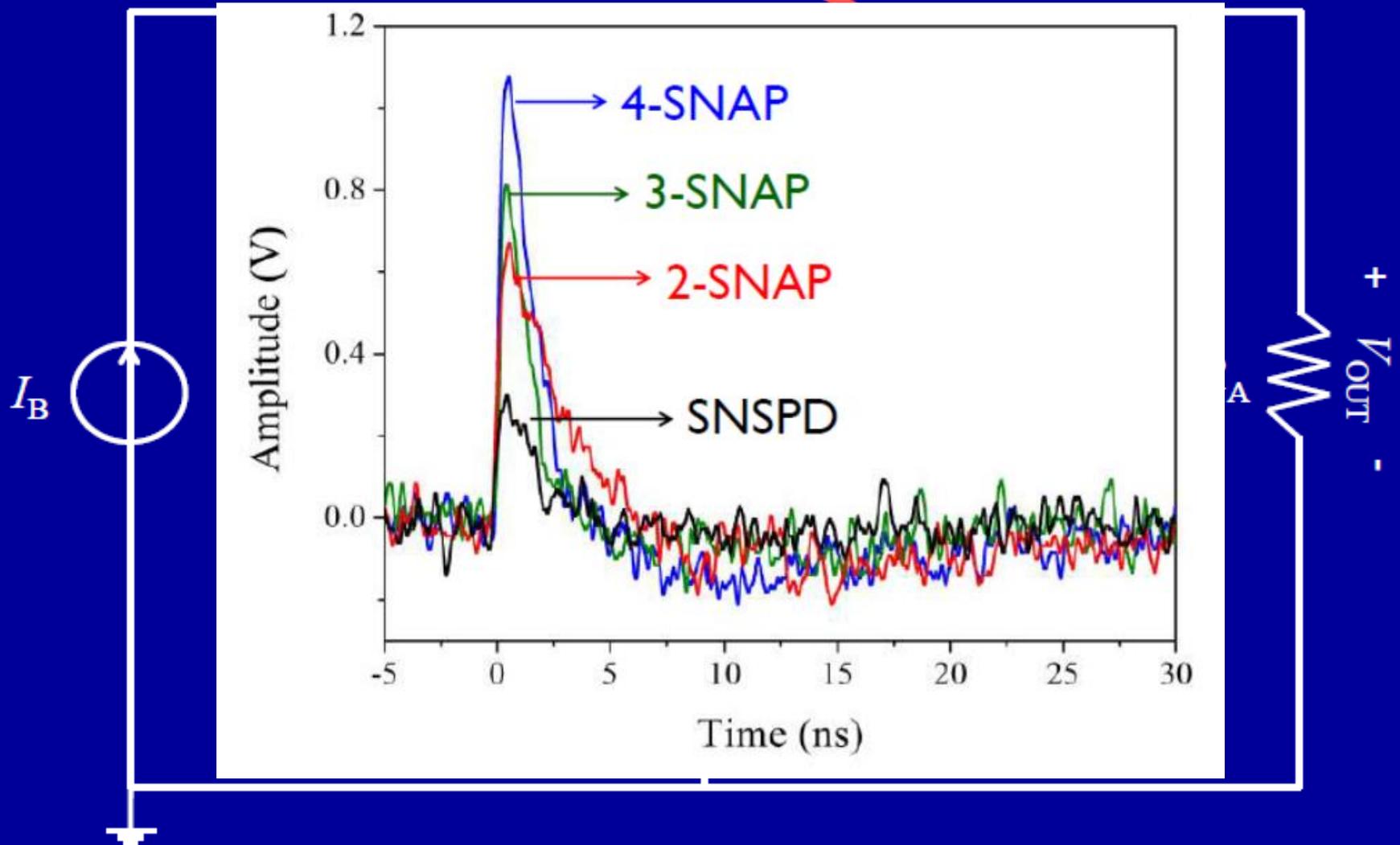
Low signal to noise ratio



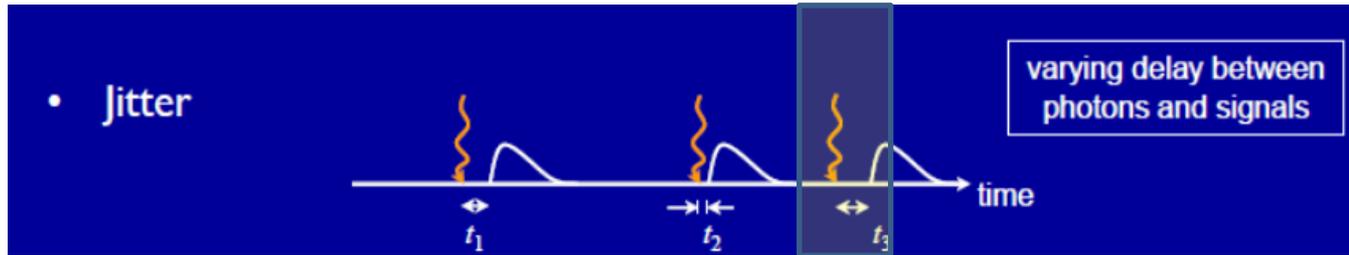
Basic model of SNAP operation



Basic model of SNAP operation



The timing Jitter



The timing jitter TJ is the variation in the time span between the photon absorption and the appearance of an output voltage pulse

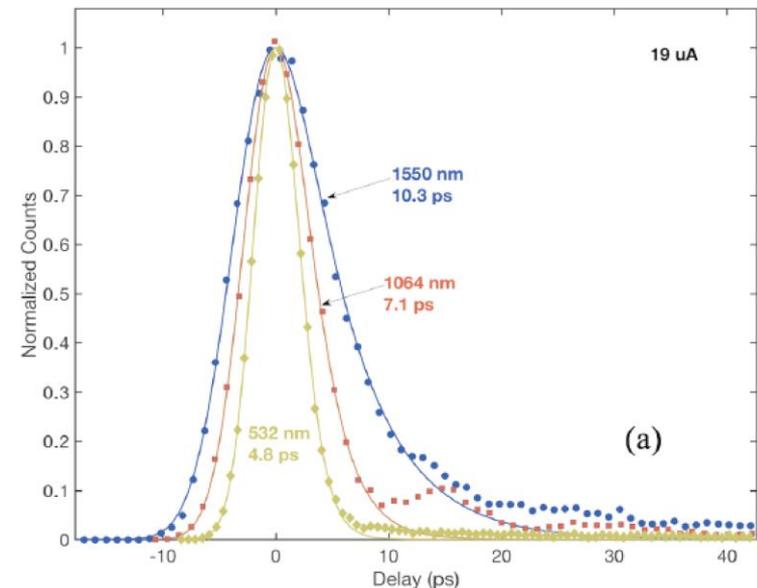
The TJ of a SNSPD depends on

- (a) the equilibrium between electrons and phonons in the energy cascade;
- (b) the order parameter time $\tau\Delta$ in $S \rightarrow N$: instability generates phase-slip lines or vortices (dissipative);
- (c) the nucleation and expansion of the N domain (dissipative);

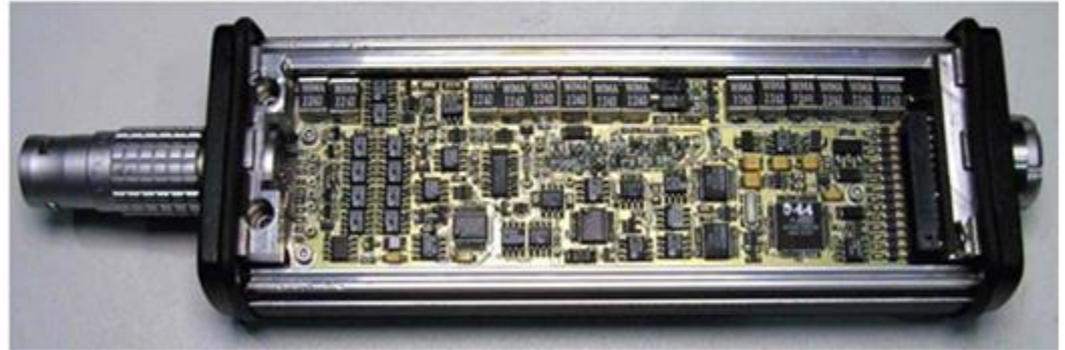
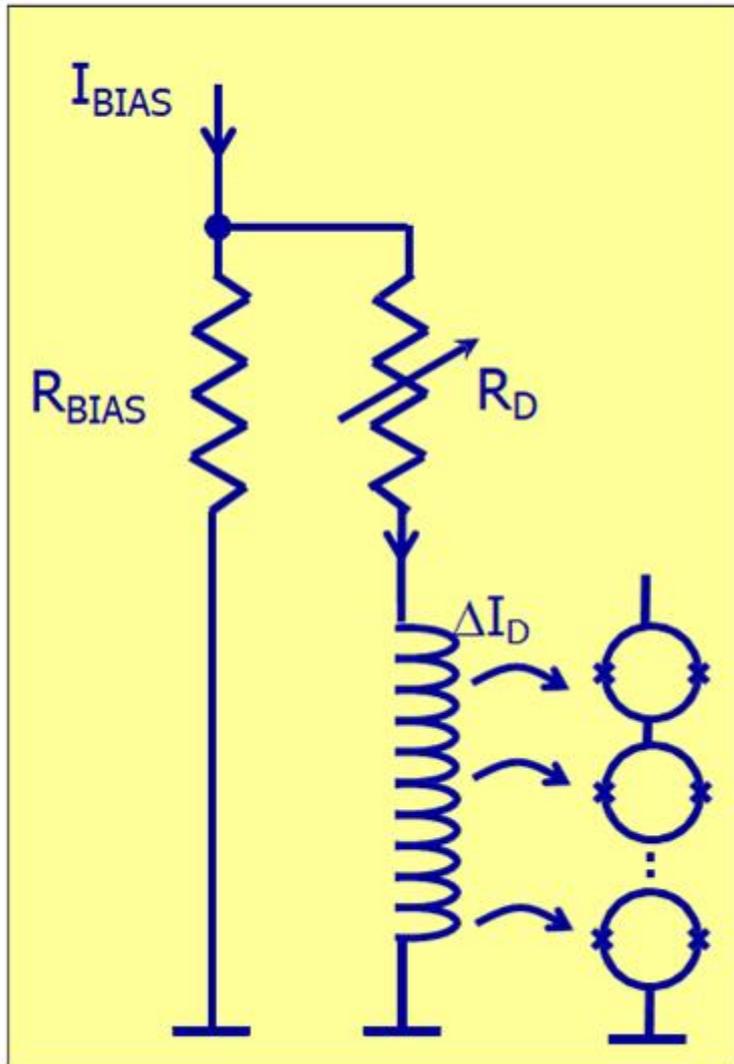
The rate of N growth influences electrical noise, and hence TJ through the signal rising edge.

Intrinsic TJ < 5 ps

JPL FW3F.3, CLEO 2018



SSPD - SQUID Readout Scheme



SQUID-Amplifier from PTB Berlin

Now in Naples, @Dept Physics... <https://seeqc.eu/>

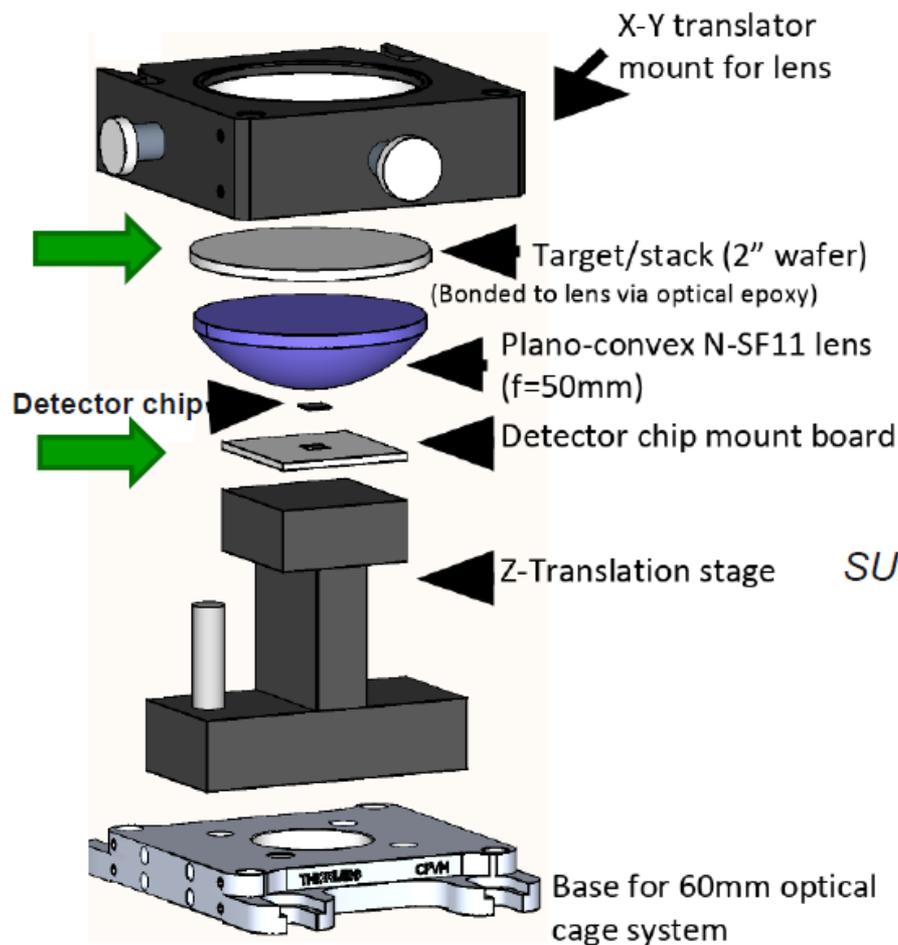


SeeQC.EU Superconducting Quantum Technologies

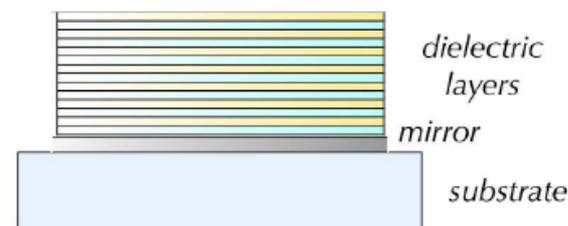
SNSPD - Experimental Setup

Multilayer optical haloscope

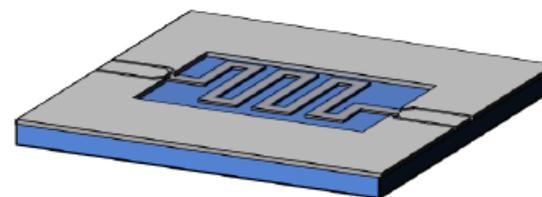
@MIT



MULTILAYER OPTICAL TARGET

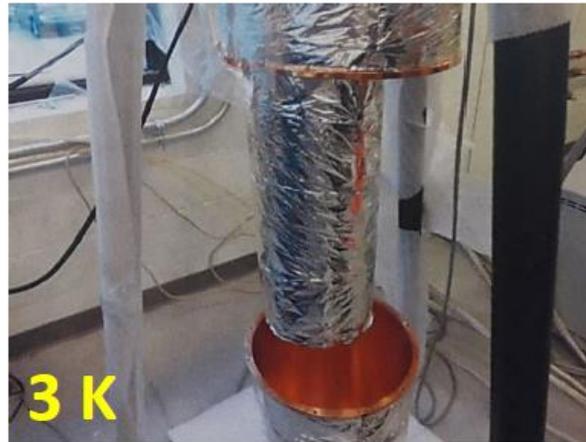
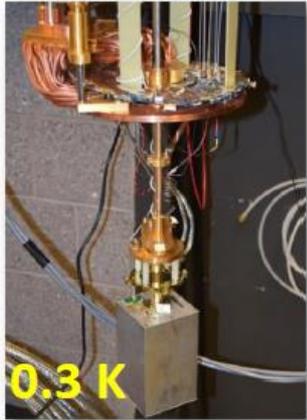


SUPERCONDUCTING NANOWIRE SINGLE-PHOTON DETECTOR (SNSPD)



SNSPD - Experimental Setup

@MIT

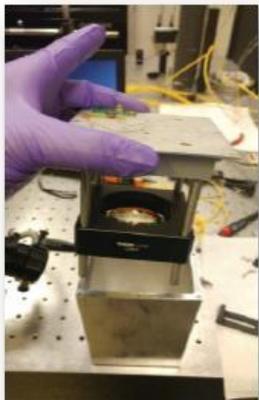


Assembled haloscope
with device prototype



Optical fiber connection removed

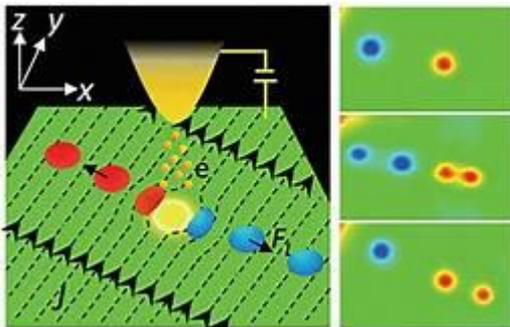
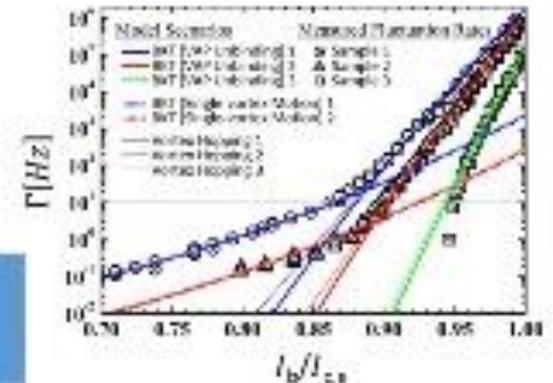
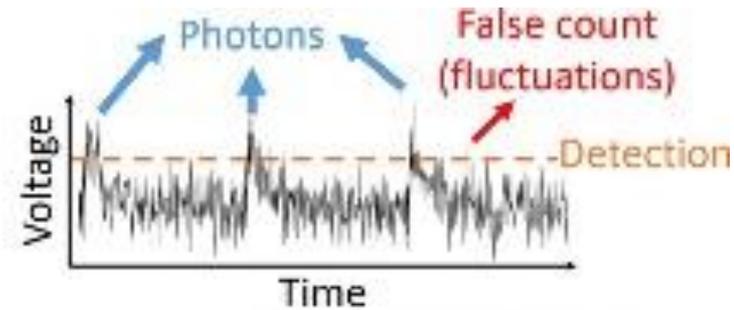
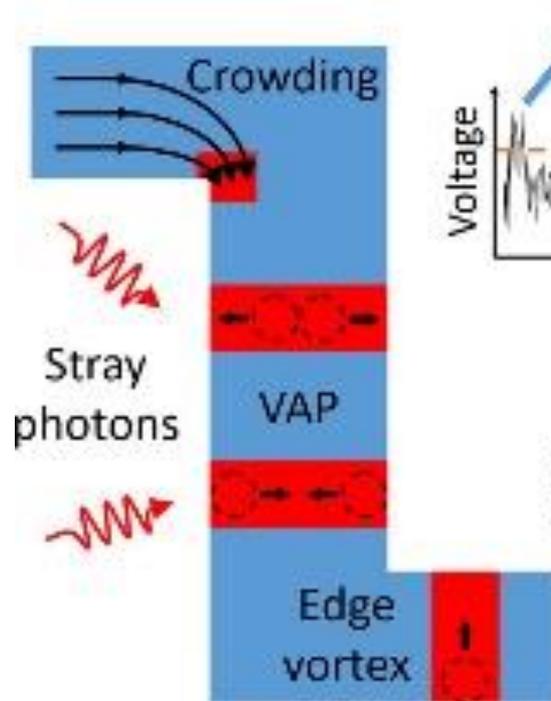
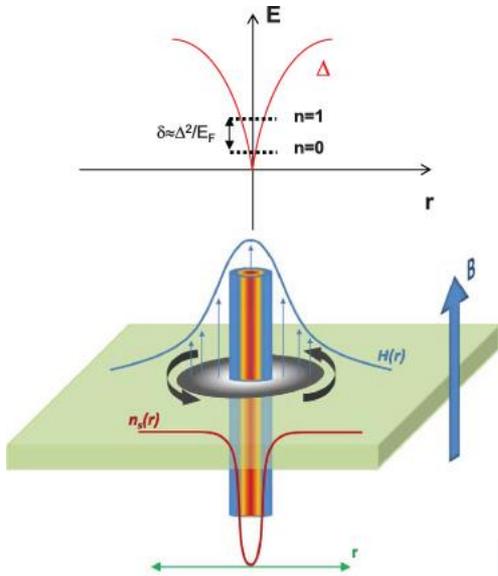
Multi-layer superinsulation (apr. 100 layers
in total) on 3 K and 40 K radiation shields



Origin of Dark count rate

- Dark count rate

voltage pulses with no corresponding photon



Origin of Dark count rate

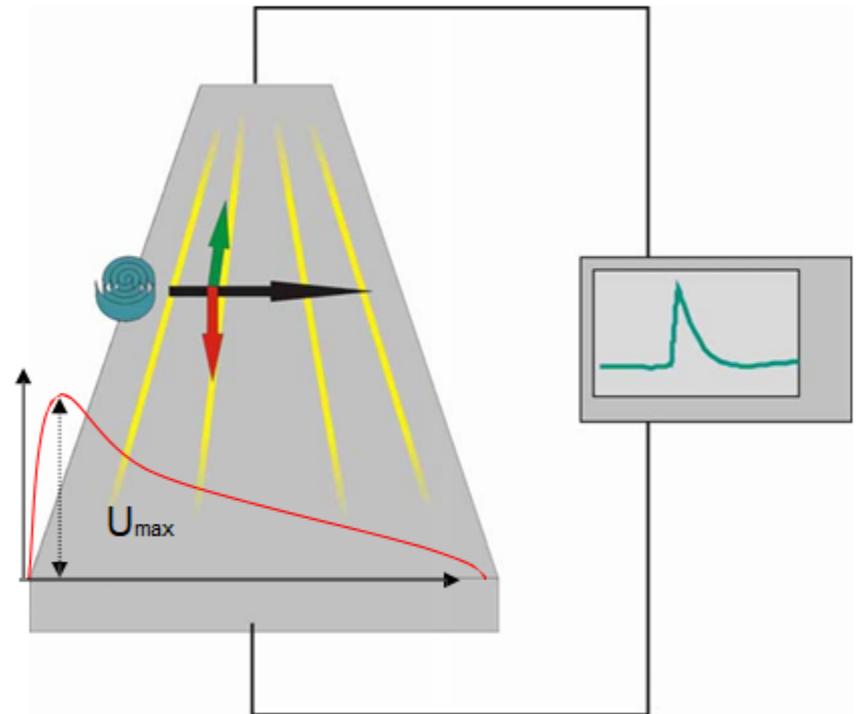
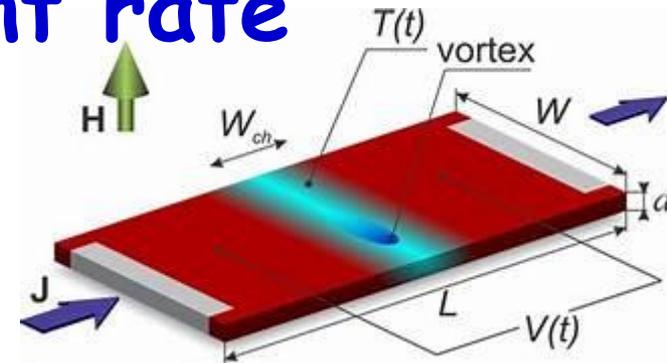
Vortex Mechanism

- Potential barrier avoids nucleation and crossing of vortices.
 - Certain probability exists that vortex nevertheless nucleates due to thermal activation.
 - Absorbed photon delivers photon energy and reduces linearly potential barrier.
- Probability increases

$$P \propto I_B \exp\left(-\frac{U_{pot,max}}{k_B T}\right)$$

$$k_B T \ll U_{pot,max}$$

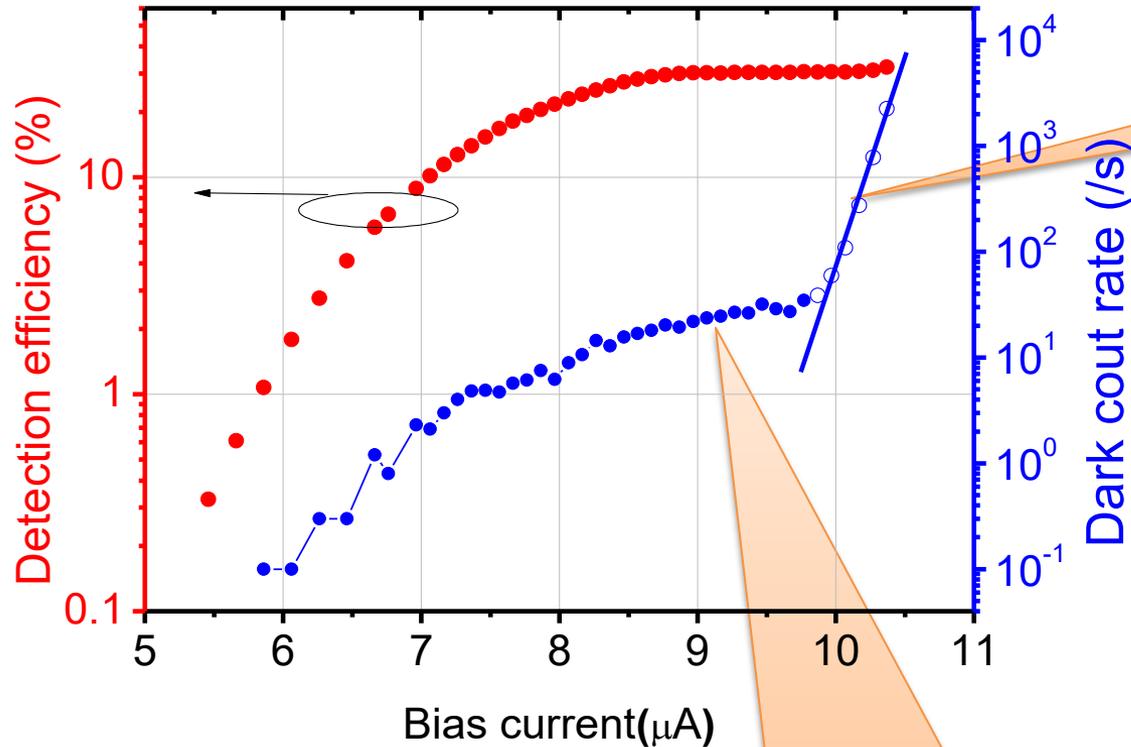
$$U_{pot,max} = f(\Phi_0, \lambda, d, w, \Delta)$$



After nucleation, vortex is swept by Lorentz force and causes a pulse.

Origin of Dark count rate

DE & DCR vs Bias Current



✓ Vortex-related

✓ Blackbody Radiation of fiber

Where we are...where w're going

Fabrication of high quality superconducting ultrathin films for SNSPDs: NbN, MoSi, MoRe

Nanopatterning of <20x20 um² area SNSPDs also in collaboration with CNR IFN Rome, Chalmers University -> nanofabrication upgrade *in progress*

Measurement set-up for DE nd DCR without shielding and direct fibre coupling at 4K->

- **closed-cycle 2K cryogenic system quipped with two SNSPDs lines optimized at different wavelenghts, i.e. <1550nm and up to 2300nm;**
- **fibre optic line within a TRITON cryo system for measurements down to 20mK;**
- **possibility of developing superconducting read-out electronics within the SeeQC_EU collaboration.**

Possibility to cover within scientific collaborations with quantum optics groups

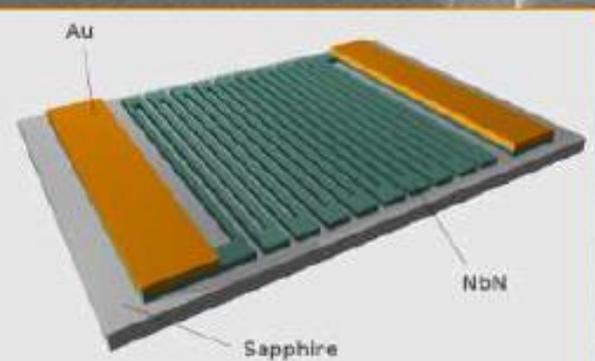
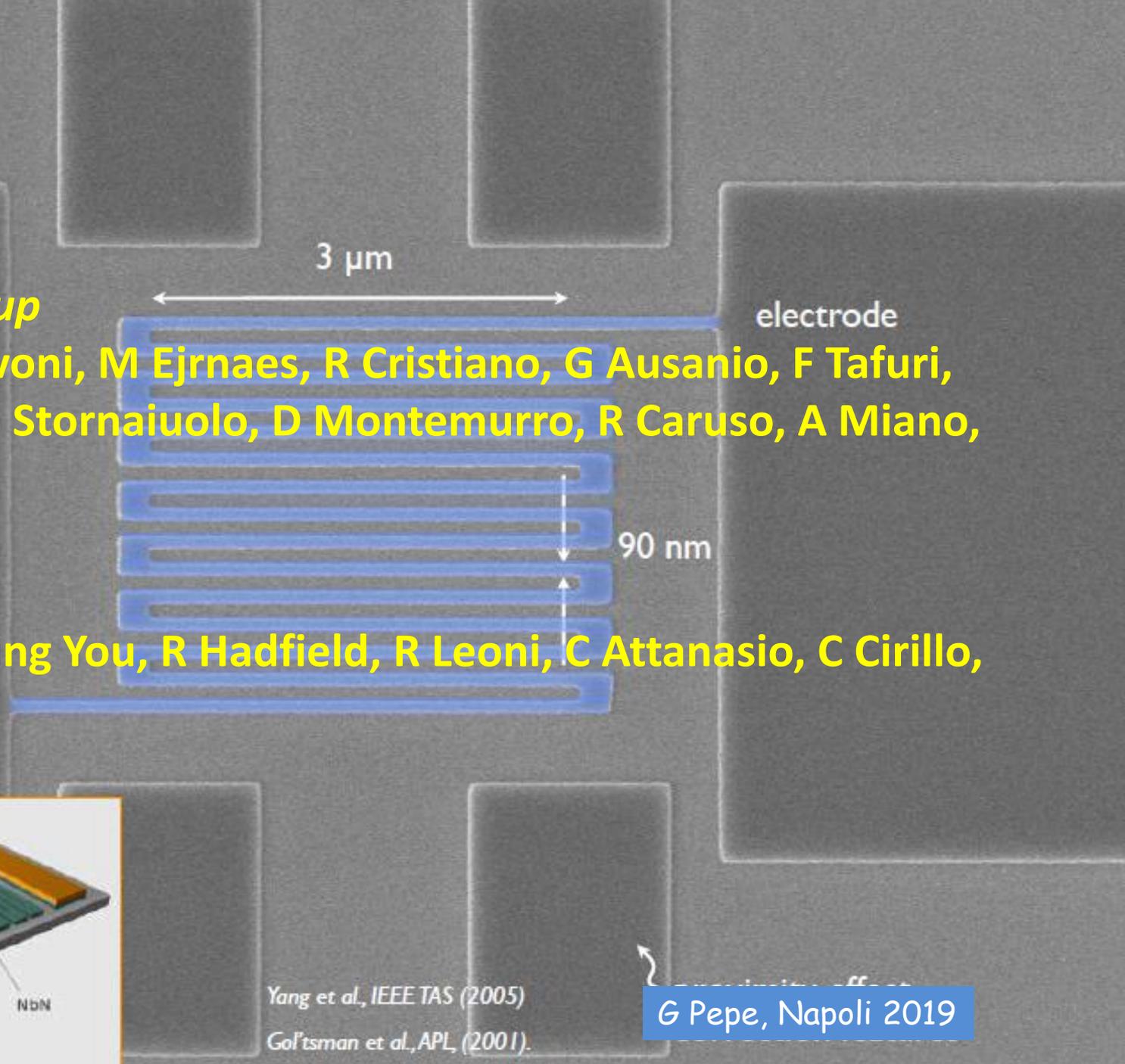
Thanks

The Naples group

L Parlato, D Salvoni, M Ejrnaes, R Cristiano, G Ausanio, F Tafuri,
D Massarotti, D Stornaiuolo, D Montemurro, R Caruso, A Miano,
H Ahmad

Collaborations:

F Lombardi, Lixing You, R Hadfield, R Leoni, C Attanasio, C Cirillo,
R Sobolewski

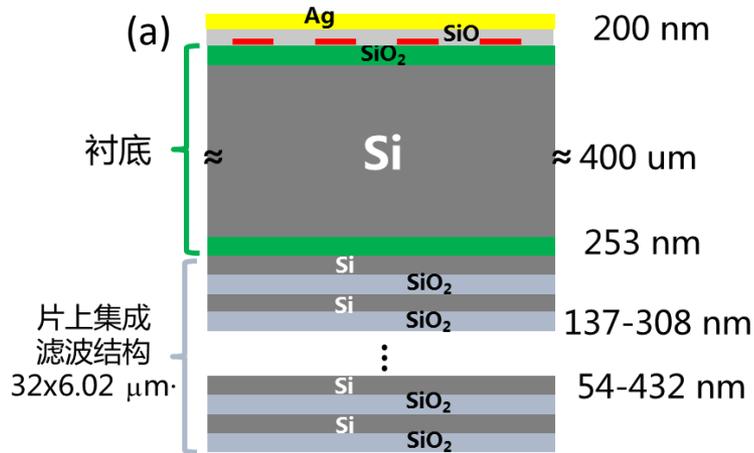


Yang et al., IEEE TAS (2005)

Gol'tsman et al., APL, (2001).

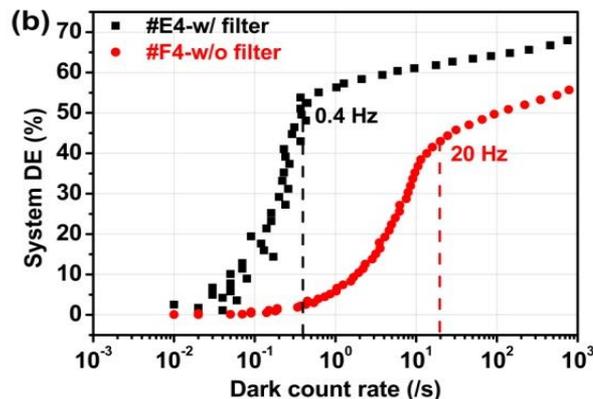
G Pepe, Napoli 2019

How to suppress thermal DCR

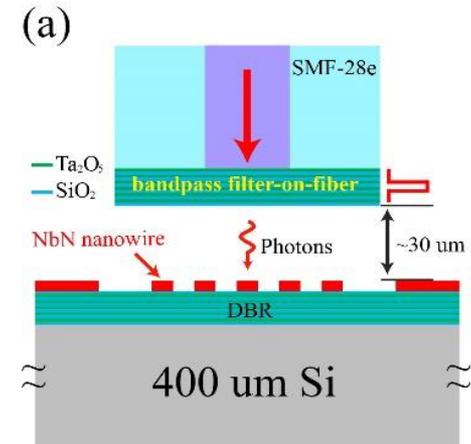


Onchip filter on backside

OE 22, 16267 (2014) Patents in CN, USA, JP

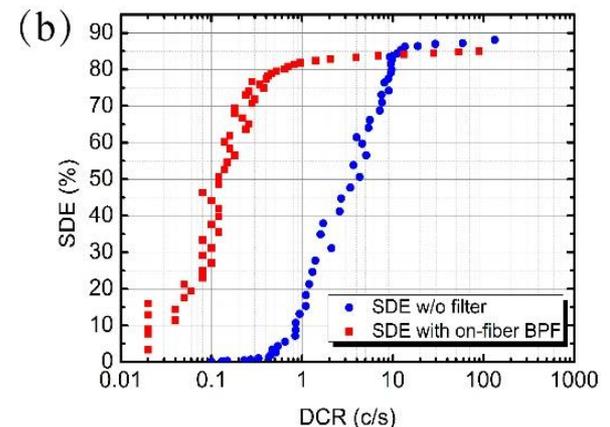


DE56% @ DCR 0.4 Hz @ Y2014



Filter on fiber tip

SUST 2018



DE80% @ DCR 1 Hz @ Y2017

G Pepe, Napoli 2019